19-2866; Rev 1; 11/09

EVALUATION KIT AVAILABLE

Multiple-Output Power-Supply Controllers for LCD Monitors

General Description

The MAX1530/MAX1531 multiple-output power-supply controllers generate all the supply rails for thin-film transistor (TFT) liquid-crystal display (LCD) monitors. Both devices include a high-efficiency, fixed-frequency, step-down regulator. The low-cost, all N-channel, synchronous topology enables operation with efficiency as high as 93%. High-frequency operation allows the use of small inductors and capacitors, resulting in a compact solution. The MAX1530 includes three linear regulator controllers and the MAX1531 includes five linear regulator controllers for supplying logic and LCD bias voltages. A programmable startup sequence enables easy control of the regulators.

The MAX1530/MAX1531 include soft-start functions to limit inrush current during startup. An internal step-down converter current-limit function and a versatile overcurrent shutdown protect the power supplies against fault conditions. The MAX1530/MAX1531 use a current-mode control architecture, providing fast load transient response and easy compensation. An internal linear regulator provides MOSFET gate drive and can be used to power small external loads.

The MAX1530/MAX1531 can operate from inputs as high as 28V and are well suited for LCD monitor and TV applications running directly from AC/DC wall adapters. Both devices are available in a small (5mm x 5mm), ultra-thin (0.8mm), 32-pin QFN package and operate over the -40°C to +85°C temperature range.

Applications

LCD Monitors and TVs

Automotive LCDs

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX1530ETJ+	-40°C to +85°C	32 TQFN-EP*
MAX1530ETJ+T	-40°C to +85°C	32 TQFN-EP*
MAX1531ETJ+	-40°C to +85°C	32 TQFN-EP*
MAX1531ETJ+T	-40°C to +85°C	32 TQFN-EP*
MAX1531ETJ/V+	-40°C to +85°C	32 TQFN-EP*
MAX1531ETJ/V+T	-40°C to +85°C	32 TQFN-EP*

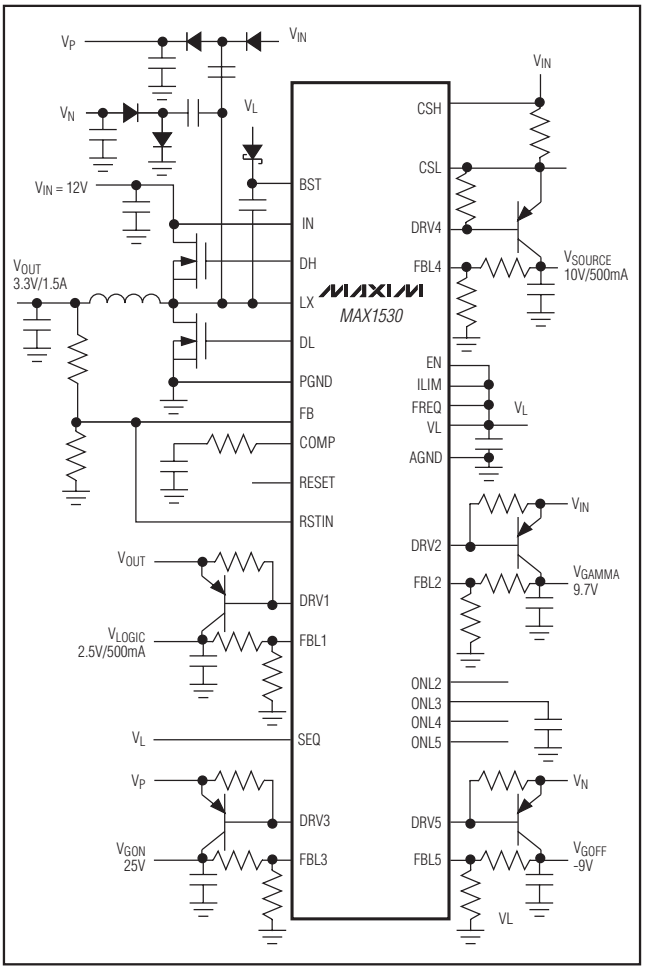
**EP = Exposed pad.*
+Denotes lead(Pb)-free/RoHS-compliant package.
/V indicates an automotive-qualified part.
T *indicates tape and reel.*

Pin Configuration appears at end of data sheet.

Features

- **4.5V to 28V Input Voltage Range**
- **250kHz/500kHz Current-Mode Step-Down Converter**
  Small Inductor/Capacitors
  No Sense Resistor
- **Three Positive Linear Regulator Controllers**
  One Positive and One Negative Additional Controller (MAX1531)
  Small Input and Output Capacitors
- **Timed Reset Output**
- **Uncommitted Overcurrent Protection (MAX1531)**
- **Soft-Start for All Regulators**
- **Programmable Input Undervoltage Comparator**
- **Programmable Startup Sequencing**

Minimal Operating Circuit



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Multiple-Output Power-Supply Controllers for LCD Monitors

ABSOLUTE MAXIMUM RATINGS

IN, DRV1, DRV2, DRV3, DRV4, CSH, CSL to AGND .....-0.3V to +30V
DRV5 to VL .....-28V to +0.3V
CSH to CSL .....-0.3V to +6V
VL to AGND .....-0.3V to +6V
PGND to AGND .....±0.3V
LX to BST .....-6V to +0.3V
BST to AGND .....-0.3V to +36V
DH to LX .....-0.3V to (BST + 0.3V)
DL to PGND .....-0.3V to (VL + 0.3V)
SEQ, ONL2, ONL3, ONL4, ONL5, COMP, ILIM to AGND .....-0.3V to (VL + 0.3V)
RSTIN, RESET, EN, FB, FBL1, FBL2, FBL3, FBL4, FBL5, FREQ to AGND .....-0.3V to +6V
VL Short Circuit to AGND .....Momentary
Continuous Power Dissipation (T_A = +70°C)
32-Pin Thin QFN (derate 21.3mW/°C above +70°C) ...1702mW
Operating Temperature Range .....-40°C to +85°C
Storage Temperature Range .....-65°C to +150°C
Junction Temperature .....+150°C
Lead Temperature (soldering, 10s) .....+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
GENERAL					
Operating Input Voltage Range	(Note 1)	4.5		28.0	V
Quiescent Supply Current	V_{FB} = V_{FBL1} = V_{FBL2} = V_{FBL3} = V_{FBL4} = 1.5V, V_{FBL5} = 0		1.7	3.0	mA
IC Disable Supply Current	EN = AGND		200	400	µA
VL REGULATOR					
VL Output Voltage	5.5V < V_{IN} < 28V, 0 < I_{VL} < 30mA	4.75	5	5.25	V
VL Undervoltage Lockout Threshold	VL rising, 3% hysteresis	3.2	3.5	3.8	V
CONTROL AND SEQUENCE					
SEQ, FREQ Input Logic High Level		2.0			V
SEQ, FREQ Input Logic Low Level				0.6	V
SEQ, FREQ Input Leakage Current		-1		+1	µA
ONL_ Input Threshold	ONL_ rising, 25mV hysteresis	1.201	1.238	1.275	V
ONL_ Source Current	SEQ = EN = VL, $V_{ONL_}$ = 0 to 1.24V	1.8	2.0	2.2	µA
ONL_ Input Leakage Current	SEQ = EN = VL, ONL_ = VL	-500		+500	nA
ONL_ Input Discharge Clamp Resistance	SEQ = 0	800	1500	3000	Ω
EN Input Threshold	EN rising, 5% hysteresis	1.201	1.238	1.275	V
EN Input Leakage Current		-50		+50	nA
FAULT DETECTION					
FB, FBL1, FBL2, FBL3, FBL4 Undervoltage Fault Trip Level	FB, FBL1, FBL2, FBL3, FBL4 falling, 25mV hysteresis	1.081	1.114	1.147	V
FBL5 Undervoltage Fault Trip Level	FBL5 rising, 25mV hysteresis	300	400	500	mV

ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Comparator Bandwidth	For EN, FB, FBL_		10		kHz
Duration to Trigger Fault Latch	For FB, FBL_	51	64	77	ms
Overcurrent Protection Threshold	(V_{CSH} - V_{CSL})	270	300	330	mV
Overcurrent Sense Common-Mode Range	V_{CSH}, V_{CSL}	2.7		28.0	V
CSH Input Current	V_{CSH} = 2.7V to 28V			100	µA
CSL Input Current	V_{CSL} = V_{CSH} = 12V	-50		+50	nA
Overcurrent Sense Filter RC Time Constant			50		µs
THERMAL PROTECTION					
Thermal Shutdown	Temperature rising, 15°C hysteresis		160		°C
RESET FUNCTION					
RSTIN Reset Trip Level	RSTIN falling, 25mV hysteresis	1.081	1.114	1.147	V
RSTIN Input Leakage Current	V_{RSTIN} = 1.5V	-50		+50	nA
Comparator Bandwidth			10		kHz
Reset Timeout Period		102	128	154	ms
RESET Output Low Level	I_{RESET} = -1mA			0.4	V
RESET Output High Leakage	V_{RESET} = 5V			1	µA
STEP-DOWN CONTROLLER					
ERROR AMPLIFIER					
FB Regulation Voltage		1.223	1.238	1.253	V
Transconductance	FB to COMP	70	100	140	µS
Voltage Gain	FB to COMP		200		V/V
Minimum Duty Cycle			15		%
FB Input Leakage Current	V_{FB} = 1.5V	-50		+50	nA
FB Input Common-Mode Range	(Note 2)	-0.1		+1.5	V
COMP Output Minimum Voltage	V_{FB} = 1.5V		1		V
COMP Output Maximum Voltage	V_{FB} = 1.175V		3		V
Current-Sense Amplifier Voltage Gain	V_{IN} - V_{LX}	2.75	3.5	4.0	V/V
Current-Limit Threshold (Default Mode)	PGND - LX, ILIM = VL	190	250	310	mV
Current-Limit Threshold (Adjustable Mode)	PGND - LX, V_{ILIM} = 1.25V	190	250	310	mV
ILIM Input Dual Mode™ Threshold		3.0	3.5	4.00	V
OSCILLATOR					
Switching Frequency	FREQ = AGND	200	250	300	kHz
	FREQ = VL	425	500	575	
Maximum Duty Cycle	FREQ = AGND	75	80	88	%
	FREQ = VL	75	80	88	

Dual Mode is a trademark of Maxim Integrated Products, Inc.

Multiple-Output Power-Supply Controllers for LCD Monitors

ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
SOFT-START					
Step Size	Measured at FB		1.238 / 32		V
Period	FREQ = GND		1024 / f_{OSC}		s
	FREQ = VL		2048 / f_{OSC}		
FET DRIVERS					
DH, DL On-Resistance			3	10	Ω
DH, DL Output Drive Current	Sourcing or sinking, V_{DH} or V_{DL} = V_{VL} / 2		0.5		A
LX, BST Leakage Current	V_{BST} = V_{LX} = V_{IN} = 28V			20	µA
LINEAR REGULATOR CONTROLLERS					
POSITIVE LINEAR REGULATOR (LR1)					
FBL1 Regulation Voltage	V_{DRV1} = 5V, I_{DRV1} = 100µA	1.226	1.245	1.264	V
FBL1 Input Bias Current	V_{FBL1} = 1.5V	-50		+50	nA
FBL1 Effective Load Regulation Error (Transconductance)	V_{DRV1} = 5V, I_{DRV1} = 100µA to 2mA		-1.5	-2	%
FBL1 Line Regulation Error	I_{DRV1} = 100µA, 5.5V < V_{IN} < 28V			5	mV
DRV1 Sink Current	V_{FBL1} = 1.175V, V_{DRV1} = 5V	3	10		mA
DRV1 Off-Leakage Current	V_{FBL1} = 1.5V, V_{DRV1} = 28V		0.1	10	µA
FBL1 Input Common-Mode Range	(Note 2)	-0.1		+1.5	V
Soft-Start Step Size	Measured at FBL1		1.238 / 32		V
Soft-Start Period	FREQ = GND		1024 / f_{OSC}		s
	FREQ = VL		2048 / f_{OSC}		
POSITIVE LINEAR REGULATORS (LR2 AND LR3)					
FBL_ Regulation Voltage	$V_{DRV_}$ = 5V, $I_{DRV_}$ = 100µA	1.226	1.245	1.264	V
FBL_ Input Bias Current	$V_{FBL_}$ = 1.5V	-50		+50	nA
FBL_ Effective Load Regulation Error (Transconductance)	$V_{DRV_}$ = 5V, $I_{DRV_}$ = 50µA to 1mA		-1.5	-2	%
FBL_ Line Regulation Error	$I_{DRV_}$ = 100µA, 5.5V < V_{IN} < 28V			5	mV
DRV_ Sink Current	$V_{FBL_}$ = 1.175V, $V_{DRV_}$ = 5V	2	4		mA
DRV_ Off-Leakage Current	$V_{FBL_}$ = 1.5V, $V_{DRV_}$ = 28V		0.1	10	µA
FBL_ Input Common-Mode Range	(Note 2)	-0.1		+1.5	V
Soft-Start Step Size	Measured at FBL_		1.238 / 32		V

ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Soft-Start Period	FREQ = GND		1024 / f_{OSC}		s
	FREQ = VL		2048 / f_{OSC}		
POSITIVE LINEAR REGULATOR (LR4)					
FBL4 Regulation Voltage	V_{DRV4} = 5V, I_{DRV4} = 500µA	1.226	1.245	1.264	V
FBL4 Input Bias Current	V_{FBL4} = 1.5V	-50		+50	nA
FBL4 Effective Load Regulation Error (Transconductance)	V_{DRV4} = 5V, I_{DRV4} = 500µA to 10mA		-1.5	-2	%
FBL4 Line Regulation Error	I_{DRV4} = 500µA, 5.5V < V_{IN} < 28V			5	mV
DRV4 Sink Current	V_{FBL4} = 1.175V, V_{DRV4} = 5V	10	28		mA
DRV4_Off-Leakage Current	V_{FBL4} = 1.5V, V_{DRV4} = 28V		0.1	10	µA
FBL4 Input Common-Mode Range	(Note 2)	-0.1		+1.5	V
Soft-Start Step Size	Measured at FBL4		1.238 / 32		V
Soft-Start Period	FREQ = GND		1024 / f_{OSC}		s
	FREQ = VL		2048 / f_{OSC}		
NEGATIVE LINEAR REGULATOR (LR5)					
FBL5 Regulation Voltage	V_{DRV5} = -10V, I_{DRV5} = 100µA	100	125	150	mV
FBL5 Input Bias Current	V_{FBL5} = 0	-50		+50	nA
FBL5 Effective Load Regulation Error (Transconductance)	V_{DRV5} = -10V, I_{DRV5} = 50µA to 1mA		-1.5	-2	%
FBL5 Line Regulation Error	I_{DRV5} = 100µA, 5.5V < V_{IN} < 28V			5	mV
DRV5 Source Current	V_{FBL5} = 200mV, V_{DRV5} = -10V	2	9		mA
DRV5 Off-Leakage Current	V_{FBL5} = 0, V_{DRV5} = -20V		0.1	10	µA
FBL5 Input Common-Mode Range	(Note 2)	-0.1		+1.5	V
Soft-Start Step Size	Measured at FBL5		1.238 / 32		V
Soft-Start Period	FREQ = AGND		1024 / f_{OSC}		s
	FREQ = VL		2048 / f_{OSC}		

ELECTRICAL CHARACTERISTICS

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = -40°C to +85°C**, unless otherwise noted.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
GENERAL					
Operating Input Voltage Range	(Note 1)	4.5		28.0	V
VL REGULATOR					
VL Output Voltage	5.5V < V_{IN} < 28V, 0 < I_{VL} < 30mA	4.75		5.25	V
VL Undervoltage Lockout Threshold	VL rising, 3% hysteresis	3.2		3.8	V

Multiple-Output Power-Supply Controllers for LCD Monitors

ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1, V_{IN} = 12V, V_{EN} = V_{SEQ} = 5V, **T_A = -40°C to +85°C**, unless otherwise noted.) (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
CONTROL AND SEQUENCE					
ONL_ Input Threshold	ONL_ rising, 25mV hysteresis	1.201		1.275	V
EN Input Threshold	EN rising, 5% hysteresis	1.201		1.275	V
FAULT DETECTION					
FB, FBL1, FBL2, FBL3, FBL4 Fault Trip Level	FB, FBL1, FBL2, FBL3, FBL4 falling, 25mV hysteresis	1.081		1.147	V
FBL5 Fault Trip Level	FBL5 rising, 25mV hysteresis	300		500	mV
Overcurrent Protection Threshold	(V_{CSH} - V_{CSL})	270		330	mV
RESET FUNCTION					
RSTIN Reset Trip Level	RSTIN falling, 25mV hysteresis	1.081		1.147	V
STEP-DOWN CONTROLLER					
ERROR AMPLIFIER					
FB Regulation Voltage		1.215		1.260	V
Current-Limit Threshold (Default Mode)	PGND - LX, ILIM = VL	170		330	mV
Current-Limit Threshold (Adjustable Mode)	PGND - LX, V_{ILIM} = 1.25V	170		330	mV
LINEAR REGULATOR CONTROLLERS					
POSITIVE LINEAR REGULATOR (LR1)					
FBL1 Regulation Voltage	V_{DRV1} = 5V, I_{DRV1} = 100µA	1.220		1.270	V
FBL1 Input Bias Current	V_{FBL1} = 1.5V	-50		+50	nA
POSITIVE LINEAR REGULATORS (LR2 AND LR3)					
FBL_ Regulation Voltage	$V_{DRV_}$ = 5V, $I_{DRV_}$ = 100µA	1.220		1.270	V
FBL_ Input Bias Current	$V_{FBL_}$ = 1.5V	-50		+50	nA
POSITIVE LINEAR REGULATOR (LR4)					
FBL4 Regulation Voltage	V_{DRV4} = 5V, I_{DRV4} = 500µA	1.220		1.270	V
FBL4 Input Bias Current	V_{FBL4} = 1.5V	-50		+50	nA
NEGATIVE LINEAR REGULATOR (LR5)					
FBL5 Regulation Voltage	V_{DRV5} = -10V, I_{DRV5} = 100µA	100		150	mV
FBL5 Input Bias Current	V_{FBL5} = 0	-50		+50	nA
DRV5 Source Current	V_{FBL5} = 200mV, V_{DRV5} = -10V	2			mA

Note 1: Operating supply range is guaranteed by VL line regulation test for the range of 5.5V to 28V. Between 4.5V and 5.5V, the V_L regulator might be in dropout; however, the part continues to operate properly.

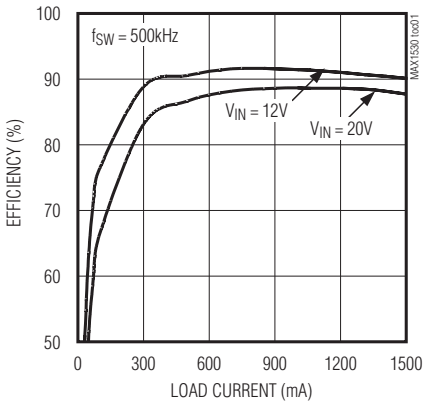
Note 2: Guaranteed by design and not production tested.

Note 3: Specifications to -40°C are guaranteed by design and not production tested.

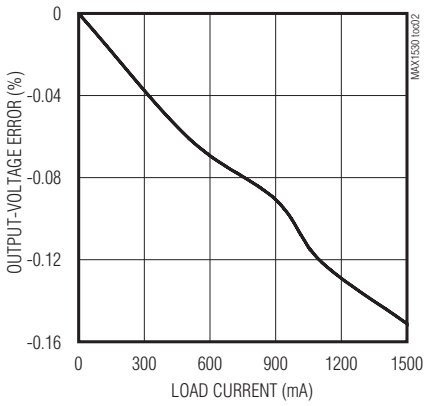
Typical Operating Characteristics

(Circuit of Figure 1; including R5, R6, and D2; T_A = +25°C, unless otherwise noted.)

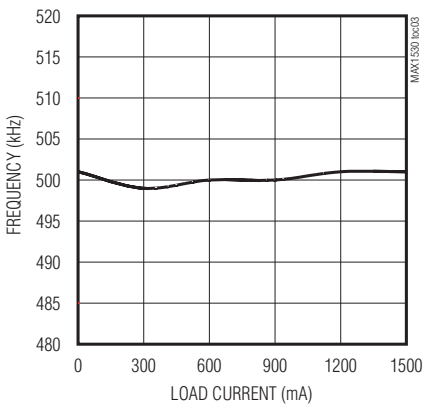
STEP-DOWN EFFICIENCY vs. LOAD CURRENT



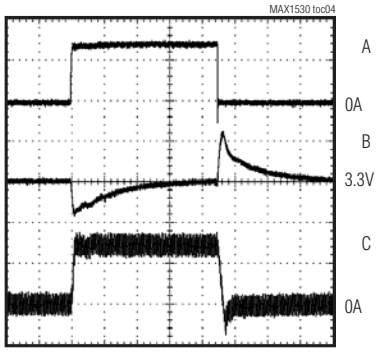
STEP-DOWN LOAD REGULATION



SWITCHING FREQUENCY vs. LOAD CURRENT

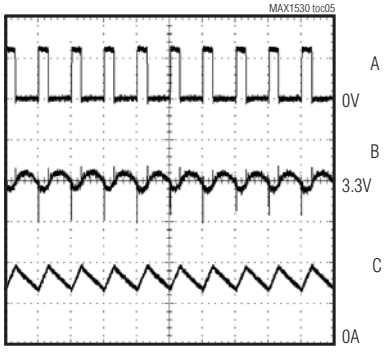


STEP-DOWN REGULATOR LOAD TRANSIENT



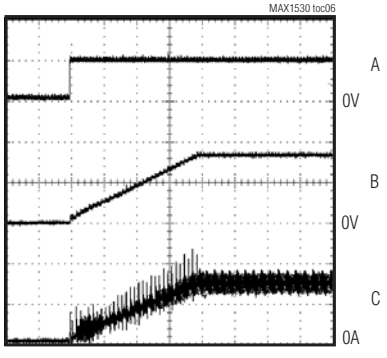
A: LOAD CURRENT, 1A/div
B: OUTPUT VOLTAGE, 200mV/div, AC-COUPLED
C: INDUCTOR CURRENT, 1A/div

STEP-DOWN REGULATOR SWITCHING WAVEFORM



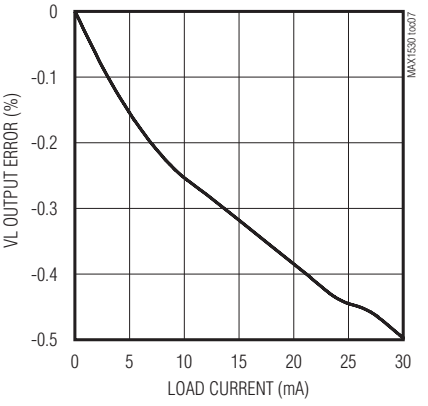
A: LX, 10V/div
B: OUTPUT VOLTAGE, 20 mV/div, AC-COUPLED
C: INDUCTOR CURRENT, 1A/div

STEP-DOWN REGULATOR SOFT-START

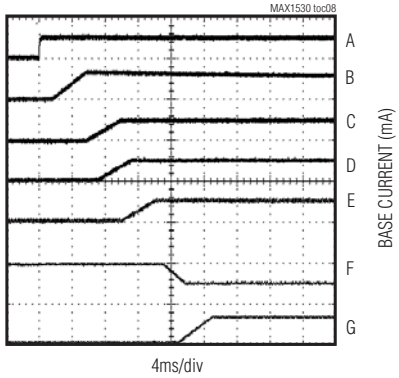


A: EN, 2V/div
B: OUTPUT VOLTAGE, 2V/div
C: INDUCTOR CURRENT, 1A/div

VL LOAD REGULATION

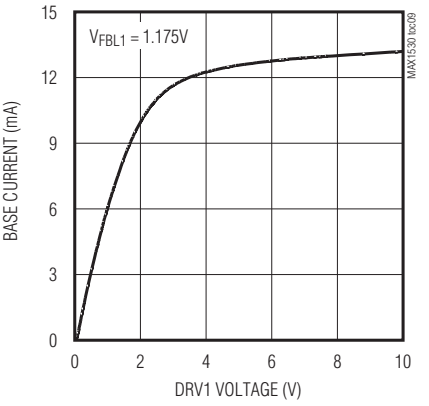


STARTUP SEQUENCE



A: V_L, 10V/div
B: V_{OUT}, 5V/div
C: V_{LOGIC}, 5V/div
D: V_{SOURCE}, 20V/div
E: V_{GAMMA}, 20V/div
F: V_{GOFF}, 20V/div
G: V_{GON}, 40V/div

LR1 BASE CURRENT vs. DRV1 VOLTAGE

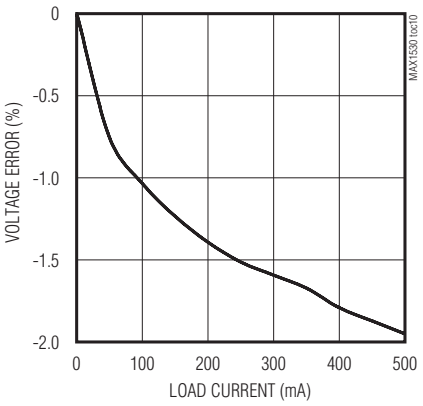


Multiple-Output Power-Supply Controllers for LCD Monitors

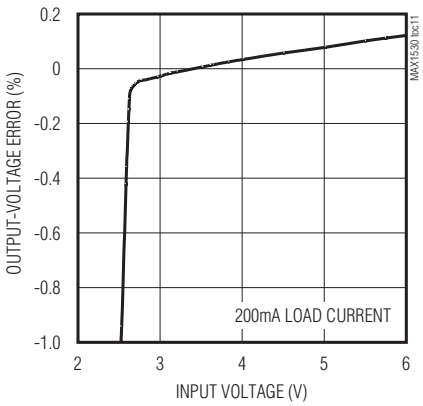
Typical Operating Characteristics (continued)

(Circuit of Figure 1; including R5, R6, and D2; T_A = +25°C, unless otherwise noted.)

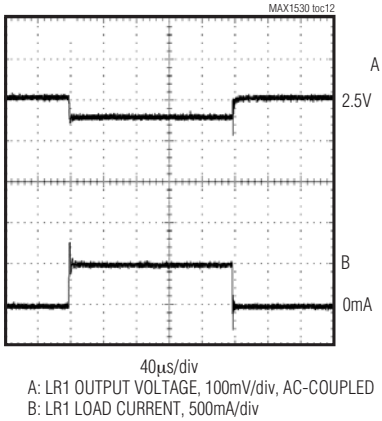
LR1 NORMALIZED LOAD REGULATION



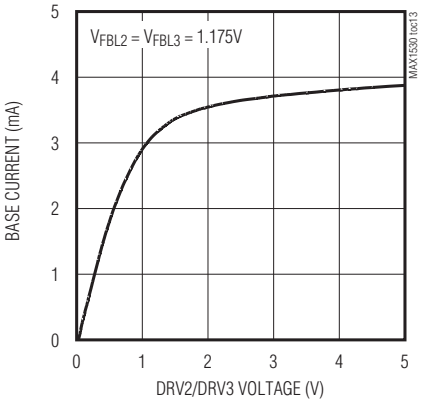
LR1 NORMALIZED LINE REGULATION



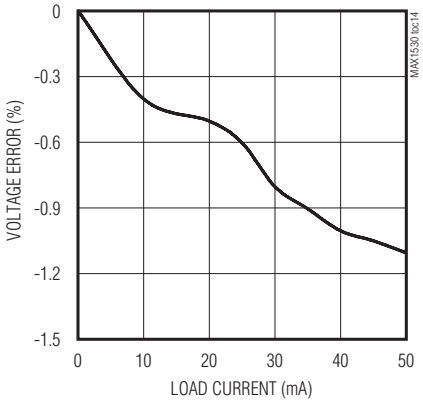
LR1 LOAD TRANSIENT



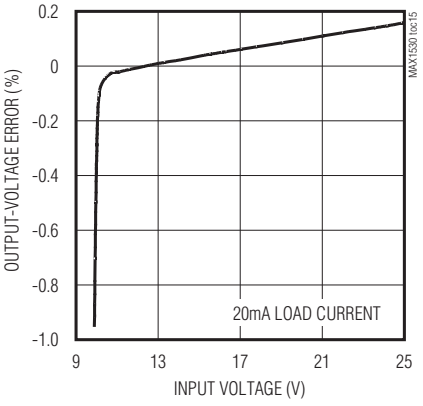
LR2/LR3 BASE CURRENT vs. DRV2/DRV3 VOLTAGE



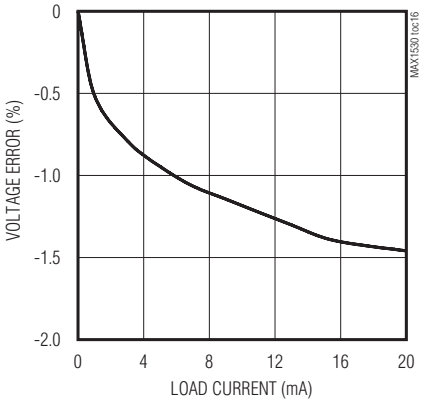
LR2 NORMALIZED LOAD REGULATION



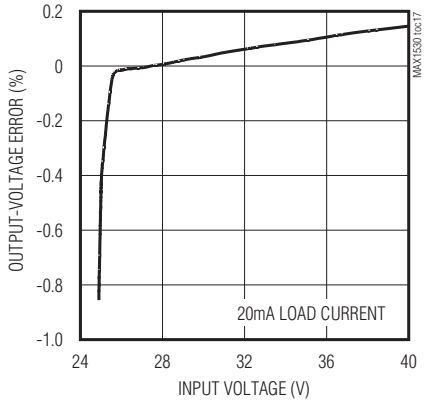
LR2 NORMALIZED LINE REGULATION



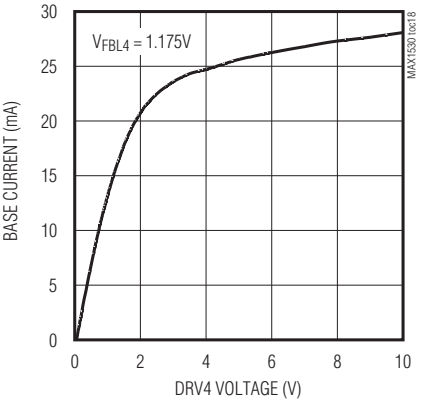
LR3 NORMALIZED LOAD REGULATION



LR3 NORMALIZED LINE REGULATION



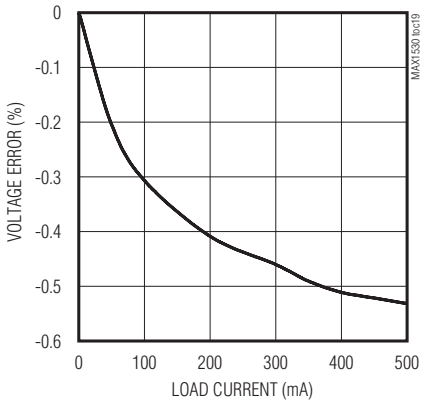
LR4 BASE CURRENT vs. DRV VOLTAGE



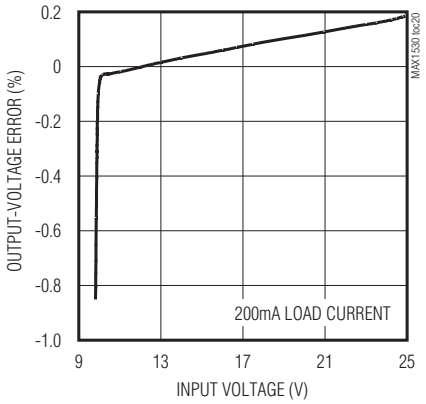
Typical Operating Characteristics (continued)

(Circuit of Figure 1; including R5, R6, and D2; T_A = +25°C, unless otherwise noted.)

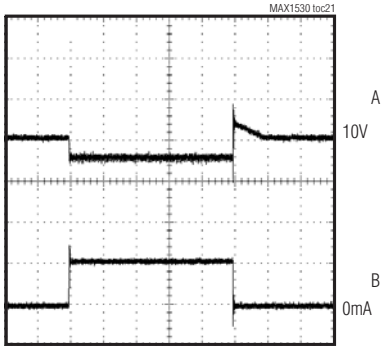
LR4 NORMALIZED LOAD REGULATION



LR4 NORMALIZED LINE REGULATION

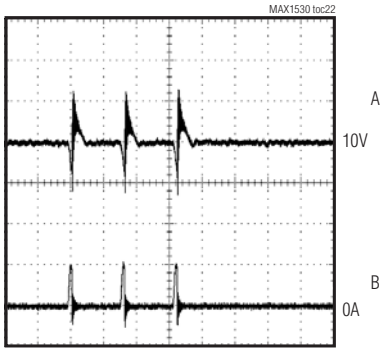


LR4 LOAD TRANSIENT



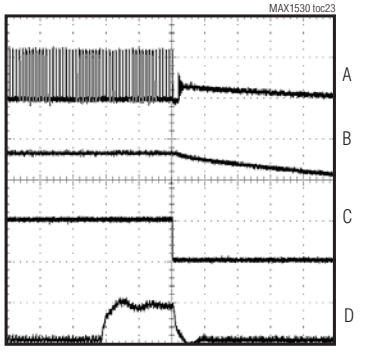
40µs/div
A: LR4 OUTPUT VOLTAGE, 100mV/div, AC-COUPLED
B: LR4 LOAD CURRENT, 500mA/div

LR4 PULSED LOAD TRANSIENT



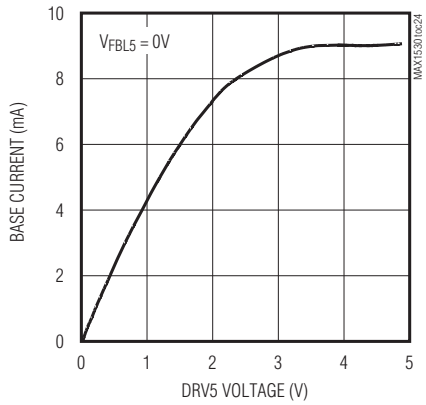
10µs/div
A: LR4 OUTPUT VOLTAGE, 100mV/div, AC-COUPLED
B: LR4 LOAD CURRENT, 1A/div

MAX1531 OVERCURRENT PROTECTION (CSH, CSL)



20µs/div
A: V_{LX}, 10V/div
B: V_{OUT}, 5V/div
C: V_{RESET}, 5V/div
D: V_{CSH} - V_{CSL}, 500mV/div

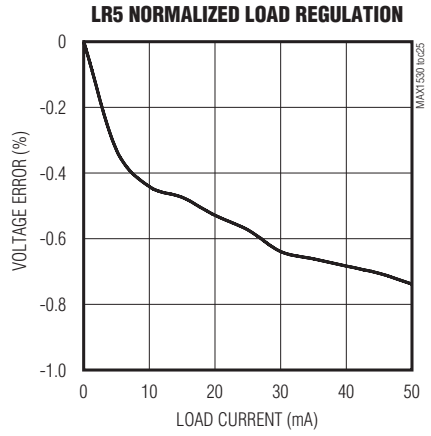
LR5 BASE CURRENT vs. DRV5 VOLTAGE

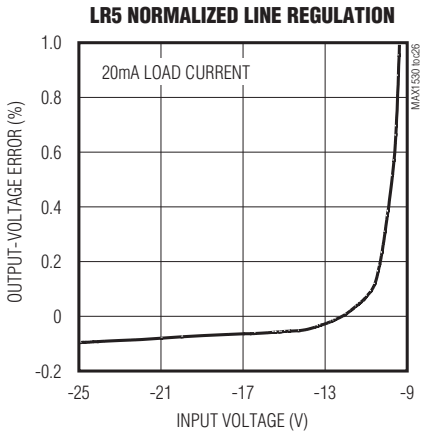


Multiple-Output Power-Supply Controllers for LCD Monitors

Typical Operating Characteristics (continued)

(Circuit of Figure 1; including R5, R6, and D2; T_A = +25°C, unless otherwise noted.)





Pin Description

PIN		NAME	FUNCTION
MAX1530	MAX1531		
1	1	DRV2	Gamma Linear Regulator (LR2) Base Drive. Open drain of an internal N-channel MOSFET. Connect DRV2 to the base of an external PNP pass transistor to form a positive linear regulator. (See the *Pass Transistor Selection* section.)
2	2	FBL2	Gamma Linear Regulator (LR2) Feedback Input. FBL2 regulates at 1.245V nominal. Connect FBL2 to the center tap of a resistive voltage-divider between the LR2 output and AGND to set the output voltage. Place the divider close to the FBL2 pin.
3	3	FBL3	Gate-On Linear Regulator (LR3) Feedback Input. FBL3 regulates at 1.245V nominal. Connect FBL3 to the center tap of a resistive voltage-divider between the LR3 output and AGND to set the output voltage. Place the divider close to the FBL3 pin.
4	4	DRV3	Gate-On Linear Regulator (LR3) Base Drive. Open drain of an internal N-channel MOSFET. Connect DRV3 to the base of an external PNP pass transistor to form a positive linear regulator. (See the *Pass Transistor Selection* section.)
5–10, 18, 19	—	N. C.	No Connection. Not internally connected.
11	11	RSTIN	Adjustable Reset Input. RESET asserts low when the monitored voltage is less than the reset trip threshold. RESET goes to a high-impedance state only after the monitored voltage remains above the reset trip threshold for the duration of the reset timeout period. Connect RSTIN to the center tap of a resistive voltage-divider between the monitored output voltage and AGND to set the reset trip threshold. The internal RSTIN threshold of 90% of 1.238V allows direct connection of RSTIN to any of the device's positive feedback pins.

Pin Description (continued)

PIN		NAME	FUNCTION
MAX1530	MAX1531		
12	12	RESET	Open-Drain Reset Output. RESET asserts low when the monitored voltage is less than the reset trip threshold. RESET goes to a high-impedance state only after the monitored voltage remains above the reset trip threshold for the duration of the reset timeout period. RESET also asserts low when VL is less than the VL undervoltage lockout threshold, EN is low, or the thermal, overcurrent or undervoltage fault latches are set.
13	13	COMP	Step-Down Regulator Compensation Input. A pole-zero pair must be added to compensate the control loop by connecting a series resistor and capacitor from COMP to AGND. (See the *Compensation Design* section.)
14	14	FB	Step-Down Regulator Feedback Input. FB regulates at 1.238V nominal. Connect FB to the center tap of a resistive voltage-divider between the step-down regulator output and AGND to set the output voltage. Place the divider close to the FB pin.
15	15	ILIM	Step-Down Regulator Current-Limit Control Input. Connect this dual-mode input to VL to set the current-limit threshold to its default value of 250mV. The overcurrent comparator compares the voltage across the low-side N-channel MOSFET with the current-limit threshold. Connect ILIM to the center tap of a resistive voltage-divider between VL and AGND to adjust the current-limit threshold to other values. In adjustable mode, the actual current-limit threshold is 1/5th of the voltage at ILIM over a 0.25V to 3.0V range. The dual-mode threshold for switchover to the 250mV default value is approximately 3.5V.
16	16	ONL2	Gamma Linear Regulator (LR2) Enable Input. When EN is above its enable threshold, VL is above its UVLO threshold, and ONL2 is greater than the internal reference, LR2 is enabled. Drive ONL2 with a logic signal or, for automatic sequencing, connect a capacitor from ONL2 to AGND. If SEQ is high, EN is above its threshold, and VL is above its UVLO threshold, an internal 2µA (typ) current source charges the capacitor. Otherwise, an internal switch discharges the capacitor. Connecting various capacitors to each ONL_ pin allows the programming of the startup sequence.
17	17	ONL3	Gate-On Linear Regulator (LR3) Enable Input. When EN is above its enable threshold, VL is above its UVLO threshold, and ONL3 is greater than the internal reference, LR3 is enabled. Drive ONL3 with a logic signal or, for automatic sequencing, connect a capacitor from ONL3 to AGND. If SEQ is high, EN is above its threshold, and VL is above its UVLO threshold, an internal 2µA (typ) current source charges the capacitor. Otherwise, an internal switch discharges the capacitor. Connecting various capacitors to each ONL_ pin allows the programming of the startup sequence.
20	20	PGND	Power Ground
21	21	DL	Low-Side Gate Driver Output. DL drives the synchronous rectifier of the step-down regulator. DL swings from PGND to VL. DL remains low until VL rises above the UVLO threshold.
22	22	LX	Step-Down Regulator Current-Sense Input. The IC's current-sense amplifier inputs for current-mode control connect to IN and LX. Connect IN and LX directly to the high-side N-channel MOSFET drain and source, respectively. The low-side current-limit comparator inputs connect to LX and PGND to sense voltage across a low-side N-channel MOSFET.

Multiple-Output Power-Supply Controllers for LCD Monitors

Pin Description (continued)

PIN		NAME	FUNCTION
MAX1530	MAX1531		
23	23	DH	High-Side Gate Driver Output. DH drives the main switch of the step-down regulator. DH swings from LX to BST.
24	24	BST	Step-Down Regulator Boostrap Capacitor Connection for High-Side Gate Driver. Connect a 0.1µF ceramic capacitor from BST to LX.
25	25	SEQ	Sequence Control Input for LR2, LR3, LR4, and LR5. Controls the current sources and switches that charge and discharge the capacitors connected to the ONL_ pins.
26	26	FREQ	Oscillator Frequency Select Input. Connect FREQ to VL for 500kHz operation. Connect FREQ to AGND for 250kHz operation.
27	27	IN	Main Input Voltage (+4.5V to 28V). Bypass IN to AGND with a 1µF ceramic capacitor close to the pins. IN powers the VL linear regulator. Connect IN to the drain of the high-side MOSFET (for current sense) through a 1Ω resistor.
28	28	VL	Internal 5V Linear Regulator Output. Connect a minimum 1µF ceramic capacitor from VL to AGND. Place the capacitor close to the pins. VL can supply up to 30mA for gate drive and external loads. VL remains active when EN is low.
29	29	AGND	Analog Ground
30	30	EN	Enable Input. This general-purpose on/off control input has an accurate 1.238V (typ) rising threshold with 5% hysteresis. This allows EN to monitor an input voltage level or other analog parameter. If EN is less than its threshold, then the main step-down and all linear regulators are turned off. VL and the internal reference remain active when EN is low. The rising edge of EN clears any latched faults except for a thermal fault, which is cleared only by cycling the input power. An internal filter with a 10µs time constant prevents short glitches from accidentally clearing the fault latch.
31	31	FBL1	Low-Voltage Logic Linear Regulator (LR1) Feedback Input. FBL1 regulates at 1.245V nominal. Connect FBL1 to the center tap of a resistive voltage-divider between LR1 output AGND to set the output voltage. Place the divider close to the FBL1 pin. LR1 starts automatically after the step-down converter soft-start ends.
32	32	DRV1	Low-Voltage Logic Linear Regulator (LR1) Base Drive. Open drain of an internal N-channel MOSFET. Connect DRV1 to the base of an external PNP pass transistor. (See the *Pass Transistor Selection* section.)
—	5	CSH	Overcurrent Protection Positive Input. CSH is also the supply input for the overcurrent sense block. CSH and CSL can be used to sense any current in the application circuit and to shut the device down in an overcurrent condition. This feature is typically used to protect the main input or the input to one of the linear regulators since they do not have their own current limits. Insert an appropriate sense resistor in series with the protected input and connect CSH and CSL to its positive and negative terminals. The controller sets the fault latch when V_{CSH} - V_{CSL} exceeds the 300mV (typ) overcurrent threshold. An internal lowpass filter prevents large currents of short duration (less than 50µs) or noise glitches from setting the latch. If the overcurrent protection is not used, connect CSH and CSL to VL.
—	6	CSL	Overcurrent Protection Negative Input. See CSH above.

Pin Description (continued)

PIN		NAME	FUNCTION
MAX1530	MAX1531		
—	7	FBL4	Source Drive Linear Regulator (LR4) Feedback Input. FBL4 regulates at 1.245V nominal. Connect FBL4 to the center tap of a resistive voltage-divider between the LR4 output and AGND to set the output voltage. Place the divider close to the FBL4 pin.
—	8	DRV4	Source Drive Linear Regulator (LR4) Base Drive. Open drain of an internal N-channel MOSFET. Connect DRV4 to the base of an external PNP pass transistor to form a positive linear regulator. (See the *Pass Transistor Selection* section.)
—	9	FBL5	Gate-Off Linear Regulator (LR5) Feedback Input. FBL5 regulates at 125mV nominal. Connect FBL5 to the center tap of a resistive voltage-divider between the LR5 output and the internal 5V linear regulator output (VL) to set the output voltage. Place the divider close to the FBL5 pin.
—	10	DRV5	Gate-Off Linear Regulator (LR5) Base Drive. Open drain of an internal P-channel MOSFET. Connect DRV5 to the base of an external NPN pass transistor to form a negative linear voltage regulator. (See the *Pass Transistor Selection* section.)
—	18	ONL4	Source Drive Linear Regulator (LR4) Enable Input. When EN is above its enable threshold, VL is above its UVLO threshold, and ONL4 is greater than the internal reference, LR4 is enabled. Drive ONL4 with a logic signal or, for automatic sequencing, connect a capacitor from ONL4 to AGND. If SEQ is high, EN is above its threshold, and VL is above its UVLO threshold, an internal 2µA (typ) current source charges the capacitor. Otherwise, an internal switch discharges the capacitor. Connecting various capacitors to each ONL_ pin allows the programming of the startup sequence.
—	19	ONL5	Gate-Off Linear Regulator (LR5) Enable Input. When EN is above its enable threshold, VL is above its UVLO threshold, and ONL5 is greater than the internal reference, LR5 is enabled. Drive ONL5 with a logic signal or, for automatic sequencing, connect a capacitor from ONL5 to AGND. If SEQ is high, EN is above its threshold, and VL is above its UVLO threshold, an internal 2µA (typ) current source charges the capacitor. Otherwise, an internal switch discharges the capacitor. Connecting various capacitors to each ONL_ pin allows the programming of the startup sequence.
—	—	EP	Exposed Paddle. Internally connected to GND. Connect EP to a large ground plane to improve thermal dissipation. Do not use as the main ground connection of the IC.

Multiple-Output Power-Supply Controllers for LCD Monitors

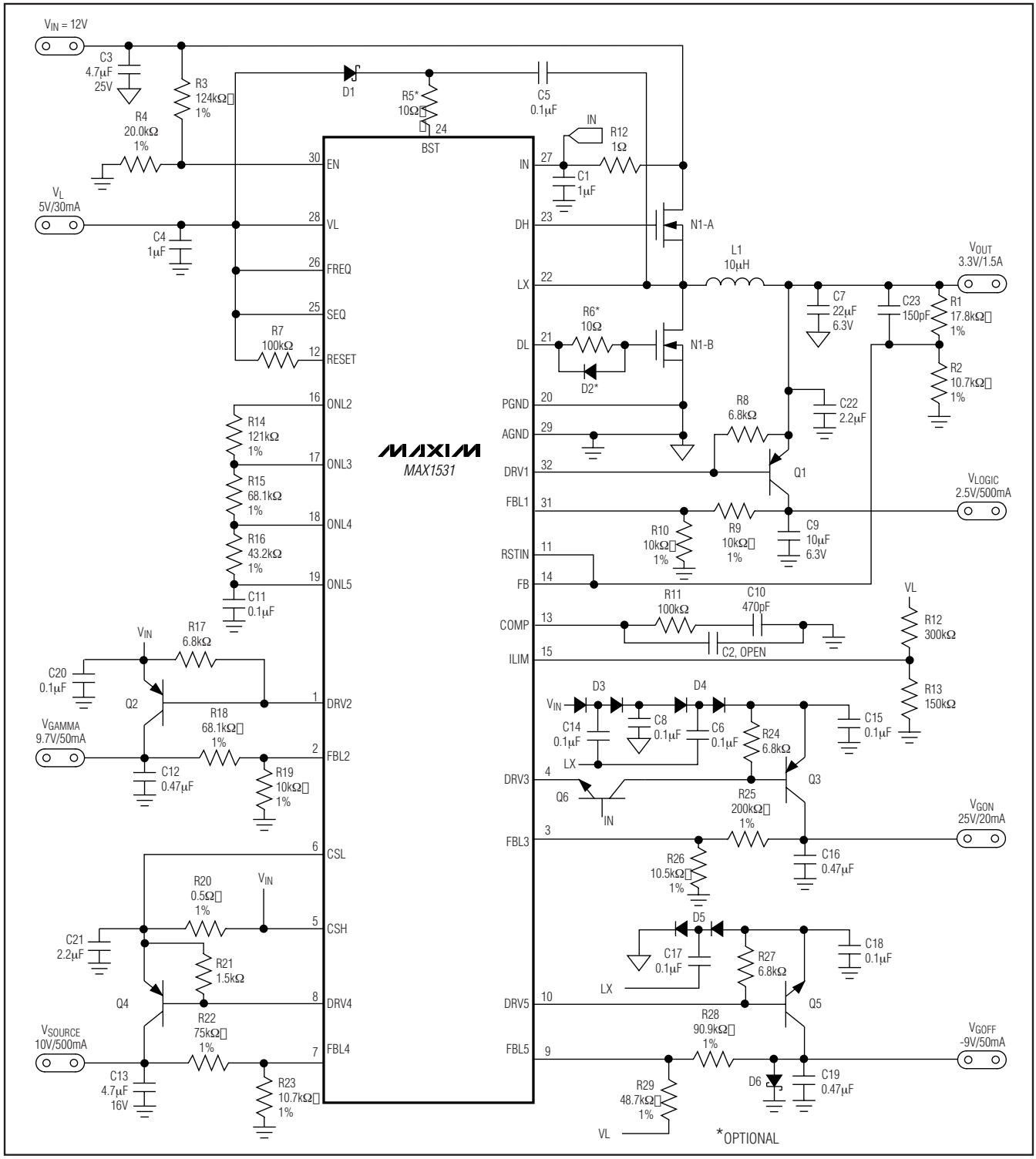


Figure 1. MAX1531 Standard Application Circuit

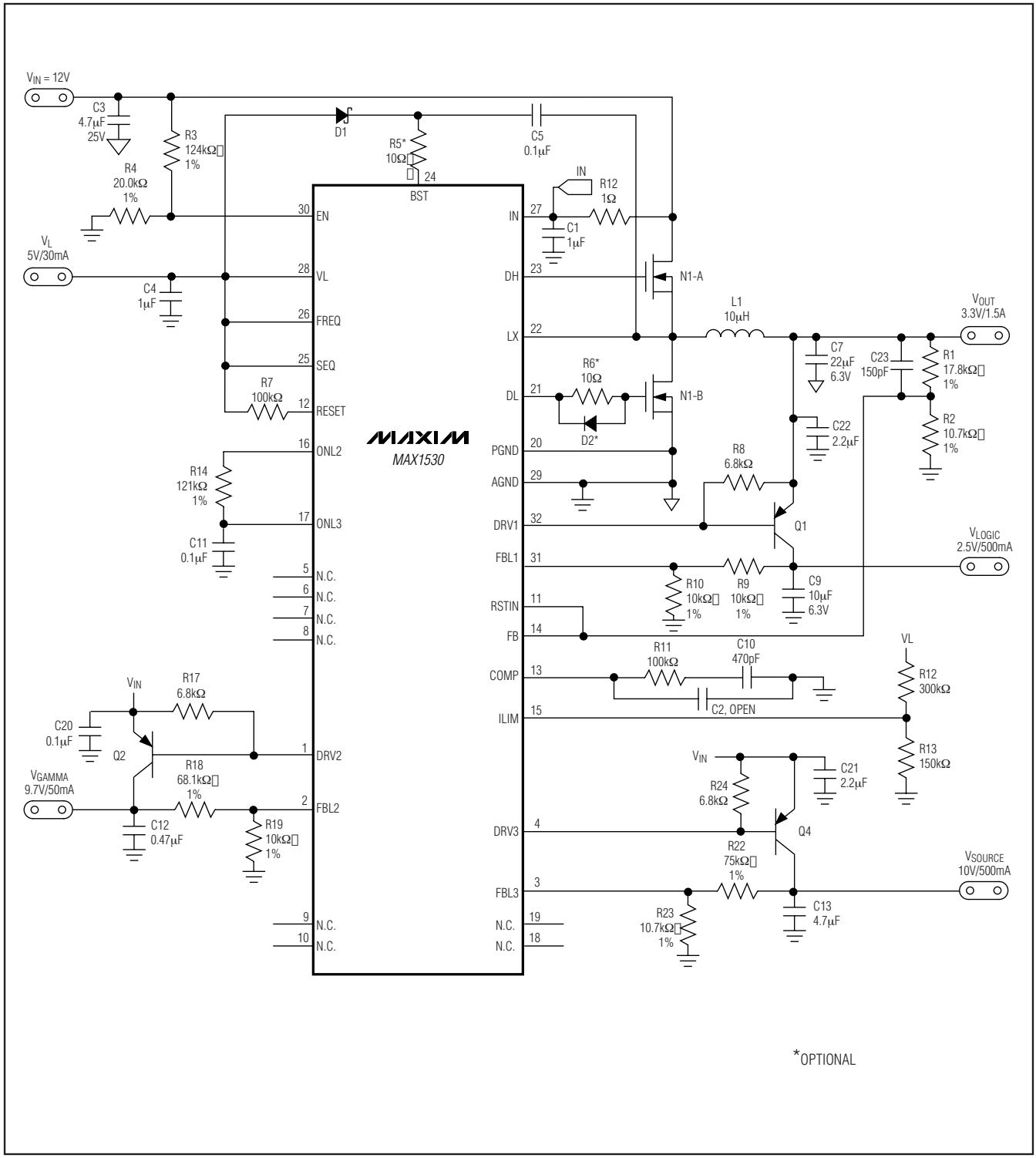


Figure 2. MAX1530 Standard Application Circuit

Multiple-Output Power-Supply Controllers for LCD Monitors

Table 1. Selected Component List

DESIGNATION	DESCRIPTION
C3	4.7µF, 25V X7R ceramic capacitor (1210) TDK C3225X7R1E475K
C7	22µF, 6.3V X7R ceramic capacitor TDK C3216X7R0J226M
C9	10µF, 6.3V X5R ceramic capacitor TDK C2012X5R0J106M
C12, C19*	0.47µF, 16V X7R ceramic capacitors (0805) TDK C2012X7R1C474K
C13	4.7µF, 16V X7R ceramic capacitor TDK C3216X7R1C475K
C21, C22	2.2µF, 25V X7R ceramic capacitors (1206) TDK C3216X7R1C475M
D1, D6*	100mA, 30V Schottky diodes (SOD523) Central Semiconductor CMOSH-3
D2	100mA, 75V, small-signal switching diode, SOT23 Fairchild Semiconductor MMBD4148
D3*, D4*, D5*	200mA, 25V dual Schottky diodes (SOT23) Fairchild BAT54S
L1	10µH, 2.3A (DC) inductor Sumida CDR7D28MN-100
N1	2.5A, 30V dual N-channel MOSFET (6-pin Super SOT) Fairchild FDC6561AN
Q1, Q4	3A, 60V low-saturation PNP bipolar transistors (SOT-223) Fairchild NZT660A
Q2, Q3*	200mA, 40V PNP bipolar transistors (SOT23) Fairchild MMBT3906
Q5*, Q6*	200mA, 40V NPN bipolar transistors (SOT23) Fairchild MMBT3904

**For MAX1531 only.*

Table 2. Component Suppliers

SUPPLIER	PHONE	FAX	WEBSITE
Central Semi	516-435-1110	516-435-1824	www.centralsemi.com
Fairchild	888-522-5372	972-910-8036	www.fairchildsemi.com
Sumida	847-956-0666	847-956-0702	www.sumida.com
TDK	847-803-6100	847-390-4405	www.components.tdk.com

Standard Application Circuit

The standard application circuit (Figure 1) of the MAX1531 is a complete power-supply system for TFT LCD monitors. The circuit generates a 3.3V/1.5A main output, a 2.5V/500mA output for the timing controller and digital sections of source/gate drive ICs, a 10V/500mA source drive supply voltage, a 9.7V/50mA gamma reference, a 25V/20mA gate-on voltage, and a -10V/50mA gate-off voltage. The input voltage is 12V ±10%. Table 1 lists the selected components and Table 2 lists the component suppliers. The standard application circuit (Figure 2) of the MAX1530 is similar to the MAX1531 application circuit except that gate-on and gate-off voltages are eliminated.

Detailed Description

The MAX1530/MAX1531 power-supply controllers provide logic and bias power for LCD monitors. Figure 3 shows the IC functional diagram. The main step-down controller employs a current-mode PWM control method to ease compensation requirements and provide excellent load- and line-transient response. The use of synchronous rectification yields excellent efficiency.

The MAX1530 includes three analog gain blocks to control three auxiliary positive linear regulators, and the MAX1531 includes five analog gain blocks to control four positive and one negative linear regulators. Use the positive gain blocks to generate low-voltage rails directly from the input voltage or the main step-down converter output, or higher voltages using charge

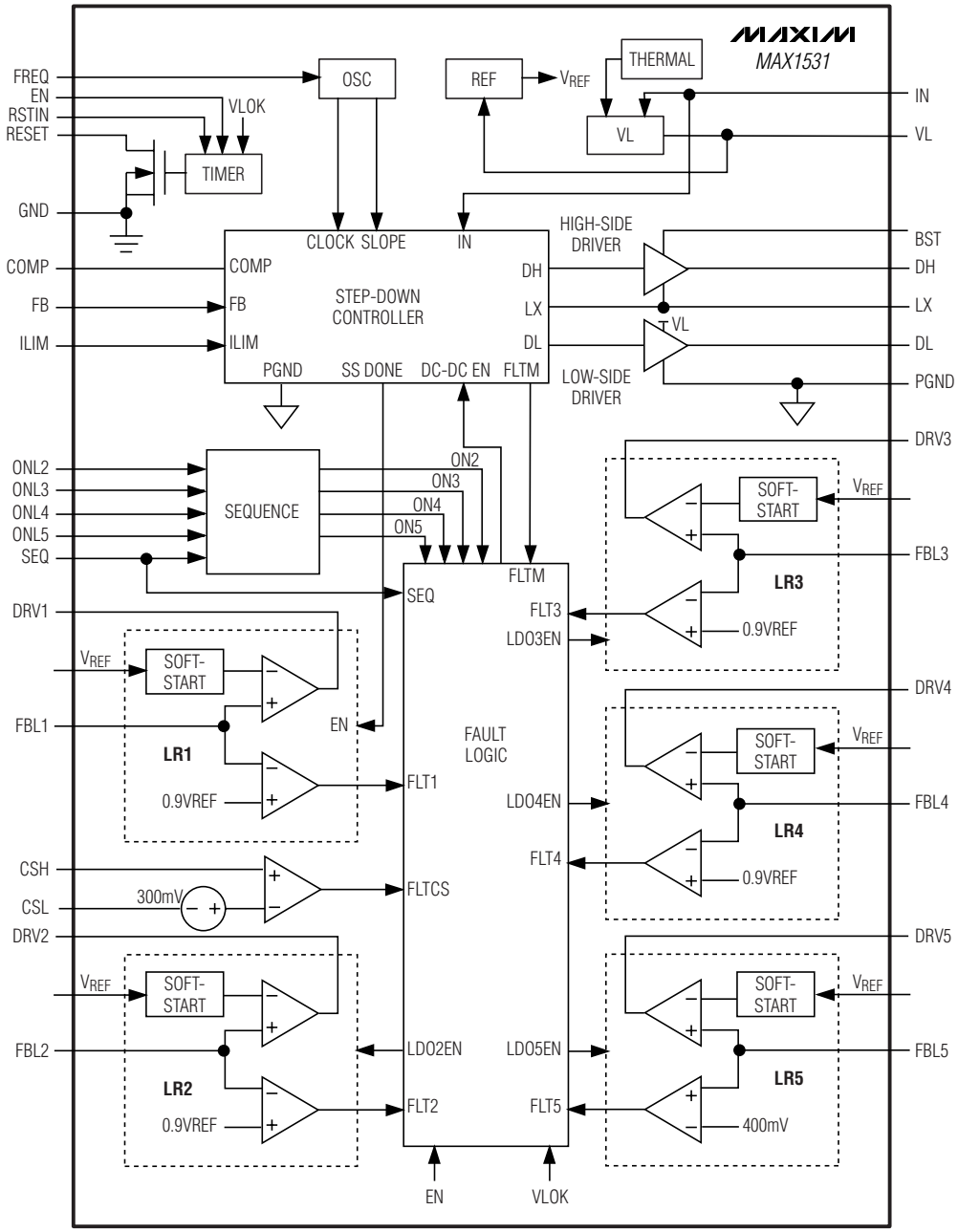


Figure 3. IC Functional Diagram

Multiple-Output Power-Supply Controllers for LCD Monitors

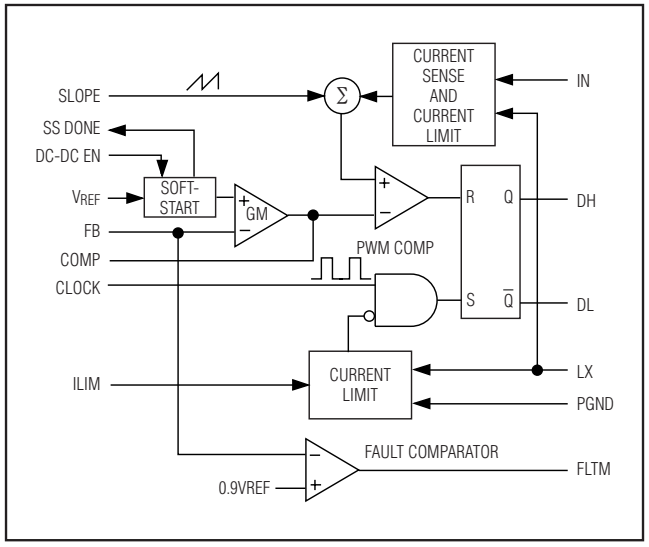


Figure 4. Step-Down Controller Block Diagram

pumps attached to the switching node or extra windings coupled to the step-down converter inductor. The negative gain block (MAX1531) can be used in conjunction with a charge pump or coupled winding to generate the LCD gate-off voltage or other negative supplies.

Step-Down Controller

The MAX1530/MAX1531 include step-down controllers that use a fixed-frequency current-mode PWM control scheme (Figure 4). An internal transconductance amplifier establishes an integrated error voltage at the COMP pin. The heart of the current-mode PWM controller is an open-loop comparator that compares an integrated voltage-feedback signal with an amplified current-sense signal plus a slope-compensation ramp. At each rising edge of the internal clock, the high-side MOSFET turns on until the PWM comparator trips or the maximum duty cycle is reached. During this on-time, current ramps up through the inductor, sourcing current to the output and storing energy in a magnetic field. The current-mode feedback system regulates the peak inductor current as a function of the output voltage error signal. Since the average inductor current is nearly the same as the peak inductor current (assuming that the inductor value is relatively high to minimize ripple current), the circuit acts as a switch-mode transconductance amplifier. That pushes the output LC filter pole, normally found in a voltage-mode PWM, to a higher frequency. To preserve loop stability, the slope-compensation ramp is summed into the main PWM comparator.

During the second half of the cycle, the high-side MOSFET turns off and the low-side N-channel MOSFET turns on. Now the inductor releases the stored energy as its current ramps down, providing current to the output. The output capacitor stores charge when the inductor current exceeds the load current and discharges when the inductor current is lower, smoothing the voltage across the load. Under overload conditions, when the inductor current exceeds the selected current limit (see *Current Limit Circuit*), the high-side MOSFET is not turned on at the rising edge of the clock and the low-side MOSFET remains on to let the inductor current ramp down.

Under light-load conditions, the MAX1530/MAX1531 maintain a constant switching frequency to minimize cross-regulation errors in applications that use a transformer. The low-side gate-drive waveform is the complement of the high-side gate-drive waveform, which causes the inductor current to reverse under light loads.

Current-Sense Amplifier

The MAX1530/MAX1531s' current-sense circuit amplifies the current-sense voltage generated by the high-side MOSFET's on-resistance. This amplified current-sense signal and the internal slope compensation signal are summed together and fed into the PWM comparator's inverting input. Place the high-side MOSFET near the controller, and connect IN and LX to the MOSFET using Kelvin-sense connections to guarantee current-sense accuracy and improve stability.

Current-Limit Circuit

The MAX1530/MAX1531 include two current-limit circuits that use the two MOSFETs' on-resistances as current-sensing elements (Figure 4). The high-side MOSFET's voltage is used with a fixed 400mV (typ) current-limit threshold during the high-side on-times. The low-side MOSFET's voltage is used with an adjustable current-limit threshold during the low-side on-times. Using both circuits together ensures that the current is always measured and controlled.

The high-side MOSFET current limit employs a peak current limit. If the voltage across the high-side MOSFET, measured from IN to LX, exceeds the 400mV threshold during an on-time, the high-side MOSFET turns off and the low-side MOSFET turns on.

The low-side MOSFET current-limit circuit employs a "valley" current limit. If the voltage across the low-side MOSFET, measured from LX to PGND, exceeds the low-side threshold at the end of a low-side on-time, the low-side MOSFET remains on and the high-side MOSFET stays off for the entire next cycle.

The ILIM pin is a dual-mode input. When ILIM is connected to VL, a default low-side current limit of 250mV (typ) is used. If ILIM is connected to a voltage between 250mV and 3V, the low-side current limit is typically 1/5th the ILIM voltage.

The MAX1530/MAX1531s' current limits are comparatively inaccurate, since the maximum load current is a function of the MOSFETs' on-resistances and the inductor value, as well as the accuracy of the two thresholds. However, using MOSFET current sensing reduces both cost and circuit size and increases efficiency, since sense resistors are not needed.

MOSFET Gate Drivers (DH, DL)

The DH and DL drivers are optimized for driving moderate-size high-side and low-side MOSFETs. Adaptive dead-time circuits monitor the DL and DH drivers and prevent either FET from turning on until the other is fully off. This algorithm allows operation without shoot-through with a wide range of MOSFETs, minimizing delays and maintaining efficiency. When the gates are turning off, there must be low-resistance, low-inductance paths from the gate drivers to the MOSFET gates for the adaptive dead-time circuit to work properly. Otherwise, the sense circuitry in the MAX1530/MAX1531 interpret the MOSFET gate as "off" while gate charge actually remains. Use short, wide traces measuring less than 50 squares (at least 20 mil wide if the MOSFET is 1in from the device).

It is advantageous to slow down the turn-on of both gate drivers if there is noise coupling between the switching regulator and the linear regulators. The noise coupling can result in excessive switching ripple on the linear regulator outputs. Slowing down the turn-on of the gate drivers proves to be an effective way of reducing the output ripple. Take care to ensure that the turn-off times are not affected at the same time. As explained above, slowing down the turn-off times may result in shoot-through problems. In Figure 1, a 10Ω resistor (R5) is inserted in series with the BST pin to slow down the turn-on of the high-side MOSFET (N1-B) without affecting the turn-off. A 10Ω resistor (R6) is also inserted between DL and the gate of the low-side MOSFET (N1-A) to slow its turn-on. Because the gate resistor would slow down the turn-off time, connect a switching diode (D2) (such as 1N4148) in parallel with the gate resistor as shown in Figure 1 to prevent potential shoot-through.

High-Side Gate-Drive Supply (BST)

A flying-capacitor bootstrap circuit generates gate-drive voltage for the high-side N-channel switch (Figure 1). The capacitor C5 between BST and LX is alternately charged from the VL supply and placed parallel to the high-side MOSFET's gate-source terminals.

On startup, the synchronous rectifier (low-side MOSFET) forces LX to ground and charges the boost capacitor from VL through diode D1. On the second half-cycle, the switch-mode power supply turns on the high-side MOSFET by closing an internal switch between BST and DH. This provides the necessary gate-to-source voltage to turn on the high-side switch, an action that boosts the 5V gate-drive signal above the input voltage.

Oscillator Frequency Selection (FREQ)

The FREQ pin can be used to select the switching frequency of the step-down regulator. Connect FREQ to VL for 500kHz operation. Connect FREQ to AGND for 250kHz operation. The 500kHz operation minimizes the size of the inductor and capacitors. The 250kHz operation improves efficiency by 2% to 3%.

Linear Regulator Controllers

The MAX1530/MAX1531 include three positive linear regulator controllers, LR1, LR2, and LR3. These linear regulator controllers can be used with external pass transistors to regulate supplies for TFT LCDs. The MAX1531 includes an additional positive linear regulator controller (LR4) and a negative linear regulator controller (LR5).

Low-Voltage Logic Regulator Controller (LR1)

LR1 is an analog gain block with an open-drain N-channel output. It drives an external PNP pass transistor with a 6.8kΩ base-to-emitter resistor. Its guaranteed base drive sink current is at least 3mA. The regulator including transistor Q1 in Figure 1 uses a 10µF output capacitor and is designed to deliver 500mA at 2.5V.

LR1 is typically used to generate low-voltage logic supplies for the timing controller and the digital sections of the TFT LCD source/gate driver ICs.

LR1 is enabled when the soft-start of the main step-down regulator is complete. (See the *Startup Sequence (ONL_,SEQ)* section.) Each time it is enabled, the controller goes through a soft-start routine that ramps up its internal reference DAC. (See the *Soft-Start* section.)

Gamma Regulator Controller (LR2)

LR2 is an analog gain block with an open-drain N-channel output. It drives an external PNP pass transistor with a 6.8kΩ base-to-emitter resistor. Its guaranteed base drive sink current is at least 2mA. The regulator including transistor Q2 in Figure 1 uses a 0.47µF output capacitor and is designed to deliver 50mA at 9.7V.

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LR2 is typically used to generate the TFT LCD gamma reference voltage, which is usually 0.3V below the source drive supply voltage.

LR2 is enabled when the step-down regulator is enabled and the voltage on ONL2 exceeds ONL2 input threshold (1.238V typ). (See the *Startup Sequence (ONL_,SEQ)* section.) Each time it is enabled, the controller goes through a soft-start routine that ramps up its internal reference DAC. (See the *Soft-Start* section).

Linear Regulator Controller (LR3)

LR3 is an analog gain block with an open-drain N-channel output. It drives an external PNP pass transistor with a 6.8kΩ base-to-emitter resistor. Its guaranteed base drive sink current is at least 2mA. The regulator, including Q3 in Figure 1, uses a 0.47µF output capacitor and is designed to deliver 20mA at 25V. The regulator including Q3 in Figure 2 uses a 4.7µF output capacitor and is designed to deliver 500mA at 10V.

For the MAX1531 (Figure 1), LR3 is typically used to generate the TFT LCD gate driver's gate-on voltage. A sufficient input voltage can be produced using a charge-pump circuit as shown in Figure 1. Note that the voltage rating of the DRV3 output is 28V. If higher voltages are present, an external cascode NPN transistor (Q6) should be used with the emitter connected to DRV3, the base to V_{IN} (which is the connection point of C1 and R12 in Figure 1), and the collector to the base of the PNP pass transistor (Figure 1). For the MAX1530 (Figure 2), LR3 is typically used to generate the TFT LCD source drive supply voltage. The input for this regulator can come directly from the input supply, be produced from an external step-up regulator, or from an extra winding coupled to the main step-down regulator inductor.

LR3 is enabled when the step-down regulator is enabled and the voltage on ONL3 exceeds the ONL3 input threshold (1.238V typ). (See the *Startup Sequence (ONL_,SEQ)* section.) Each time it is enabled, the controller goes through a soft-start routine that ramps up its internal reference DAC. (See the *Soft-Start* section.)

Source Drive Regulator Controller (LR4) (MAX1531 Only)

LR4 is an analog gain block with an open-drain N-channel output. It drives an external PNP pass transistor with a 1.5kΩ base-to-emitter resistor. Its guaranteed base drive sink current is at least 10mA. The regulator including Q4 in Figure 1 uses a 4.7µF output capacitor and is designed to deliver 500mA at 10V. The regulator's fast transient response allows it to handle brief peak currents up to 2A.

LR4 is typically used to generate the TFT LCD source drive supply voltage. The input for this regulator can come directly from the input supply, be produced from an external step-up regulator, or from an extra winding coupled to the main step-down regulator inductor.

LR4 is enabled when the step-down regulator is enabled and the voltage on ONL4 exceeds the ONL4 input threshold (1.238V typ). (See the *Startup Sequence (ONL_,SEQ)* section.) Each time it is enabled, the regulator goes through a soft-start routine that ramps up its internal reference DAC from 0V to 1.238V (typ). (See the *Soft-Start* section.)

The standard application circuit in Figure 1 powers the LR4 regulator directly from the input supply and uses the MAX1531's general-purpose overcurrent protection function to protect the input supply from excessive load currents. (See the *Overcurrent Protection* section.)

Gate-Off Regulator Controller (LR5) (MAX1531 Only)

LR5 is an analog gain block with an open-drain P-channel output. It drives an external NPN pass transistor with a 6.8kΩ base-to-emitter resistor. Its guaranteed base drive sink current is at least 2mA. The regulator including Q5 in Figure 1 uses a 0.47µF output capacitor and is designed to deliver 10mA at -10V.

LR5 is typically used to generate the TFT LCD gate driver's gate-off voltage. A negative input voltage can be produced using a charge-pump circuit as shown in Figure 1. Use as many stages as necessary to obtain the required output voltage.

LR5 is enabled when the step-down regulator is enabled and the voltage on ONL5 exceeds the ONL5 input threshold (1.238V typ). (See the *Startup Sequence (ONL_,SEQ)* section.) Each time it is enabled, the regulator goes through a soft-start routine that ramps down its internal reference DAC from VL to 125mV (typ). (See the *Soft-Start* section.)

Internal 5V Linear Regulator (VL)

All MAX1530/MAX1531 functions, except the thermal sensor, are internally powered from the on-chip, low-dropout 5V regulator. The maximum regulator input voltage (V_{IN}) is 28V. Bypass the regulator's output (VL) with at least a 1µF ceramic capacitor to AGND. The V_{IN}-to-VL dropout voltage is typically 200mV, so when V_{IN} is less than 5.2V, VL is typically V_{IN} - 200mV. The internal linear regulator can source up to 30mA to supply the device, power the low-side gate driver, charge the external boost capacitor, and supply small external loads. When driving particularly large MOSFETs, little or no regulator current may be available for external

loads. For example, when switched at 500kHz, large MOSFETs with a total of 40nC total gate charge would require 40nC × 500kHz, which is approximately 20mA.

On/Off Control (EN)

The EN pin has an accurate 1.238V (typ) rising threshold with 5% hysteresis. The accurate threshold allows it to be used to monitor the input voltage or other analog signals of interest. If V_{EN} voltage is less than its threshold, then the step-down regulator and all linear regulators are turned off. VL and the internal reference remain active when EN is low to allow an accurate EN threshold. A rising edge on the pin clears any latched faults except for a thermal fault, which is cleared only by cycling the input power.

Undervoltage Lockout

If VL drops below 3.4V (typ), the MAX1530/MAX1531 assume that the supply voltage is too low to make valid decisions. Therefore, the undervoltage lockout (UVLO) circuitry turns off all the internal bias supplies. Switching is inhibited, and the DL and DH gate drivers are forced low. After VL rises above 3.5V (typ), the fault and thermal shutdown latches are cleared and startup begins if EN is above its threshold.

Startup Sequence (ONL_, SEQ)

The MAX1530/MAX1531 are not enabled unless all four of the following conditions are met: 1) VL exceeds the UVLO threshold, 2) EN is above 1.238V, 3) the fault latch is not set, and 4) the thermal shutdown latch is not set. After all four conditions are met, the step-down controller starts switching and enables soft-start (Figure 5). After the step-down regulator soft-start is done, the low-voltage logic linear regulator controller (LR1) soft-starts.

The remaining linear regulator controllers and the sequence block that can be used to control them are enabled at the same time as the step-down regulator. The SEQ logic input is used in combination with the ONL_ pins to control the startup sequence. When SEQ is high and the sequence block is enabled, each ONL_ pin sources 2µA (typ). When the voltage on an ONL_ pin reaches 1.238V (typ), its respective linear regulator controller (LR_) is enabled. When SEQ is low or the sequence block is not enabled, each ONL_ pin is connected to ground through a 1.5kΩ internal MOSFET.

The sequence block allows the user to program the startup of LR2 to LR5 in any desired sequence. If no capacitor is placed on an ONL_ pin, its LR_ controller starts immediately after the sequence block is enabled and SEQ goes high. Placing a 1.5nF capacitor on an ONL_ pin provides about 1ms delay for the respective

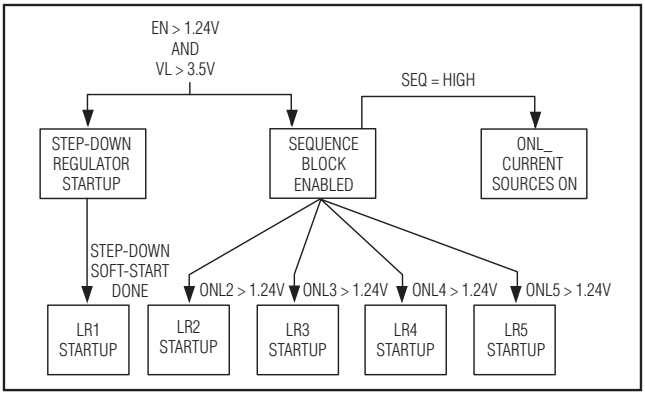


Figure 5. Startup Conditions

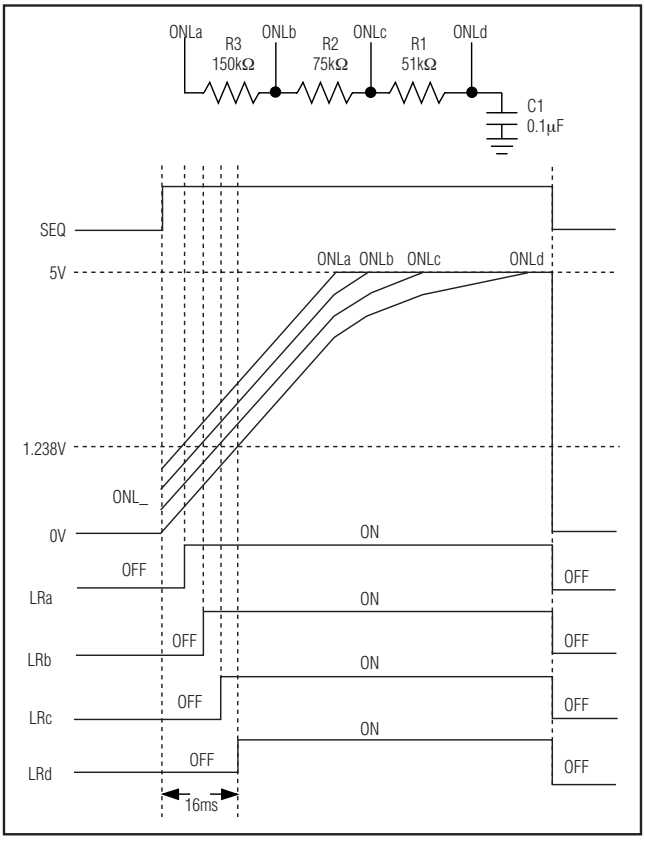


Figure 6. Single-Capacitor Sequence Configuration

LR_ controller. Placing different size capacitors on each ONL_ pin allows any arbitrary startup sequence.

An arbitrary startup sequence can also be created with a single capacitor (Figure 6). Capacitor C1, together with the 8µA current (2µA per ONL_ pin), is chosen to provide the desired delay for the controller that starts last (ONLd). Using 0.1µF for C1 provides about 16ms

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total delay. Because of the 6µA current flowing through R1 (51kΩ), the voltage on ONLc is 0.31V greater than the voltage on ONLd and it crosses the 1.238V threshold and enables its LR_ controller about 4ms before ONLd's controller. Similarly, the 4µA current through R2 (75kΩ) and the 2µA current through R3 (150kΩ) cause their LR_ controllers to each start about 4ms before the next one. Any desired sequence and delay can be programmed by calculating the charge rate of C1 and voltage drops across R1 through R3.

Soft-Start

The soft-start function controls the slew rate of the output voltages and reduces inrush currents during startup. Each regulator (step-down, LR1 to LR5) goes through a soft-start routine after it is enabled. During soft-start, the reference voltage for each positive regulator gradually ramps up from 0V to the internal reference in 32 steps. The reference voltage of the negative regulator ramps down from VL to 125mV in 32 steps. The total soft-start period for each regulator is 1024 clock cycles for 250kHz switching frequency and 2048 clock cycles for 500kHz switching frequency.

Reset

The MAX1530/MAX1531 include an open-drain timed microprocessor supervisor function to ensure proper startup of digital circuits. The RESET output asserts low whenever RSTIN is less than the RSTIN trip threshold. RESET also asserts low when VL is less than the VL UVLO threshold, EN is low, or the thermal, undervoltage or overcurrent fault latches are set. RESET enters the high-impedance state only after RSTIN remains above the trip threshold for the duration of the reset timeout period. The state of RESET has no effect on other portions of the IC.

The RSTIN threshold (1.114V typ) is designed to allow RSTIN to directly connect to any of the MAX1530/MAX1531s' feedback input pins, eliminating the need for an additional resistive divider. Typically, RSTIN is connected to FB or FBL1 to monitor the supply voltage for digital logic ICs, but it can be used to monitor any desired output voltage or it can even be used as a general-purpose comparator.

Fault Protection

Undervoltage Protection

After its soft-start is done, if the output of the main step-down regulator or any of the linear-regulator outputs (LR1 to LR5) are below 90% of their normal regulation point, the MAX1530/MAX1531 activate an internal fault timer. If the fault condition remains continuously for the entire fault timer duration, the MAX1530/MAX1531 set the fault latch, shutting down all the regulator outputs. Undervoltage faults do not turn off VL. Once the fault condition is removed, cycling the input voltage or applying a rising edge on SEQ or EN clears the fault latch and reactivates the device.

Thermal Protection

The thermal protection limits total power dissipation in the MAX1530/MAX1531. If the junction temperature exceeds +160°C, a thermal sensor immediately sets the thermal fault latch, shutting off all the IC's outputs including VL, allowing the device to cool down. The only way to clear the thermal fault latch is to cycle the input voltage after the device cools down by at least 15°C.

Overcurrent Protection Block (CSH, CSL) (MAX1531 Only)

The MAX1531 includes an uncommitted overcurrent protection block that can be used to measure any input or output current, using a current-sense resistor or other sense element. If the measured current exceeds the overcurrent protection threshold (300mV typ), the MAX1531 immediately sets the undervoltage fault latch, shutting down all the regulator outputs. Overcurrent faults do not turn off VL. An internal lowpass filter prevents large current transients of short duration (less than 50µs) from setting the latch. Once the overcurrent condition is removed, cycling the input voltage clears the fault latch and reactivates the device. A rising edge on SEQ or EN also clears the fault latch.

In Figure 1's circuit, the overcurrent protection is used with the LR4 source driver regulator since that regulator is powered directly from the input supply and has no current limit of its own. The current-sense resistor is placed in series with the input supply, before the linear regulator's external PNP pass transistor. CSH and CSL are connected to the positive and negative sides of the sense resistor.

Design Procedures

Main Step-Down Regulator

Inductor Selection

Three key inductor parameters must be specified: inductance value (L), peak current (I_{PEAK}), and DC resistance (R_{DC}). The following equation includes a constant, LIR, which is the ratio of peak-to-peak inductor ripple current to DC load current. A higher LIR value allows smaller inductance, but results in higher losses and higher ripple. A good compromise between size and losses is typically found at a 30% ripple current to

load current ratio (LIR = 0.3), which corresponds to a peak inductor current 1.15 times the DC load current:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{SW} \times I_{LOAD(MAX)} \times LIR}$$

where $I_{LOAD(MAX)}$ is the maximum DC load current, and the switching frequency f_{SW} is 500kHz when FREQ is tied to VL, and 250kHz when FREQ is tied to AGND. The exact inductor value is not critical and can be adjusted to make trade-offs among size, cost, and efficiency. Lower inductor values minimize size and cost, but they also increase the output ripple and reduce the efficiency due to higher peak currents. On the other hand, higher inductor values increase efficiency, but at some point increased resistive losses due to extra turns of wire will exceed the benefit gained from lower AC current levels.

The inductor's saturation current must exceed the peak inductor current. The peak current can be calculated by:

$$I_{RIPPLE} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{f_{SW} \times L \times V_{IN}}$$

$$I_{PEAK} = I_{LOAD(MAX)} + \frac{I_{RIPPLE}}{2}$$

The inductor's DC resistance should be low for good efficiency. Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. Ferrite cores are often the best choice, though powdered iron is inexpensive and can work well at 250kHz. Shielded-core geometries help keep noise, EMI, and switching waveform jitter low.

MOSFET Selection and Current-Limit Setting

The MAX1530/MAX1531s' step-down controller drives two external logic-level N-channel MOSFETs. Since the $R_{DS(ON)}$ of each MOSFET is used as a sense resistor to provide current-sense signals to the PWM, their $R_{DS(ON)}$ values are important considerations in component selection.

The $R_{DS(ON)}$ of the high-side MOSFET (N1) provides an inductor current-sense signal for current-mode operation and also provides a crude maximum current limit during the high-side on-time that prevents runaway currents if the inductor saturates. The MOSFET voltage is measured across the high-side MOSFET from V_{IN} to LX and is limited to 400mV (typ). To ensure the desired output current with sufficient margin, choose a MOSFET with $R_{DS(ON)}$ low enough that the peak current does not generate more than 340mV across the MOSFET, even when the MOSFET is hot. If the MOSFET's $R_{DS(ON)}$ is not specified at a suitable temperature, use the maximum room temperature specification and add 0.5% per °C for the $R_{DS(ON)}$ increase with temperature:

$$I_{PEAK} \times R_{DS(ON)_HOT} < 340mV$$

To ensure stable operation of the current-mode PWM, the minimum current-sense ripple signal should exceed 12mV. Since this value depends on the minimum $R_{DS(ON)}$ of the high-side MOSFET, which is not typically a specified parameter, a good rule of thumb is to choose the typical room temperature $R_{DS(ON)}$ about 2 times the amount needed for this:

$$I_{RIPPLE} \times R_{DS(ON)_TYP} > 24mV$$

For example, Figure 1's circuit is designed for 1.5A and uses a dual MOSFET (N1) for both the high-side and low-side MOSFETs. Its maximum $R_{DS(ON)}$ at room temperature is 145mΩ and an estimate of its maximum $R_{DS(ON)}$ at our chosen maximum temperature of +85°C is 188mΩ. Since the inductor ripple current is 0.5A, the peak current through the MOSFET is 1.75A. So the maximum peak current-sense signal is 330mV, which is less than 340mV. Using the typical $R_{DS(ON)}$ of 113mΩ and the ripple current of 0.5A, the current ripple signal for the PWM is 56mV, much greater than the required 24mV.

The $R_{DS(ON)}$ of the low-side MOSFET (also N1) provides current-limit information during the low-side on-time that inhibits a high-side on-time if the MOSFET voltage is too high. The voltage is measured across the low-side MOSFET from PGND to LX and the threshold is set by ILIM. To use the preset 250mV (typ) threshold, connect ILIM to VL and choose a MOSFET with $R_{DS(ON)}$ low enough that the "valley" current does not generate more than 190mV across the MOSFET, even when the MOSFET is hot. If the MOSFET's $R_{DS(ON)}$ is not specified at a suitable temperature, use the maximum room temperature specification and add 0.5% per °C for the $R_{DS(ON)}$ increase with temperature:

$$I_{VALLEY} = I_{OUT} - I_{RIPPLE}/2$$

$$I_{VALLEY} \times R_{DS(ON)_HOT} < 190mV$$

If the MOSFET's $R_{DS(ON)}$ is lower than necessary, there is no need to adjust the current-limit threshold using ILIM. If the MOSFET's $R_{DS(ON)}$ is too high, adjust the current-limit threshold using a resistive-divider between

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VL and AGND at ILIM. The threshold is approximately 1/5th the voltage on ILIM over a range of 0.25V to 3V:

$$I_{VALLEY} \times R_{DS(ON)_HOT} < 0.2 \times V_{ILIM} \times (1-K)$$

K is the accuracy of the current-limit threshold, which is 20% when the threshold is 250mV.

For example, Figure 1's N1 MOSFET has a maximum $R_{DS(ON)}$ at room temperature of 145mΩ and an estimate of its maximum at our chosen maximum temperature of +85°C is 188mΩ. Since the inductor ripple current is 0.5A, the valley current through the MOSFET is 1.25A. So the maximum valley current-sense signal is 235mV, which is too high to work with the 190mV minimum of the default current-limit threshold. Adding a divider at ILIM (R12 and R13) adjusts the ILIM voltage to 1.7V and the current-limit threshold to 340mV, providing more than adequate margin for threshold accuracy.

Input Capacitor

The input filter capacitor reduces peak currents drawn from the power source and reduce noise and voltage ripple on the input caused by the regulator's switching. It is usually selected according to input ripple current requirements and voltage rating, rather than capacitance value. The input voltage and load current determine the RMS input ripple current (I_{RMS}):

$$I_{RMS} = I_{LOAD} \times \frac{\sqrt{V_{OUT} \times (V_{IN} - V_{OUT})}}{V_{IN}}$$

The worst case is $I_{RMS} = 0.5 \times I_{LOAD}$, which occurs at $V_{IN} = 2 \times V_{OUT}$.

For most applications, ceramic capacitors are used because of their high ripple current and surge current capabilities. For long-term reliability, choose an input capacitor that exhibits less than +10°C temperature rise at the RMS input current corresponding to the maximum load current.

Output Capacitor

The output capacitor and its equivalent series resistance (ESR) affect the regulator's loop stability, output ripple voltage, and transient response. The *Compensation Design* section discusses the output capacitance requirement based on the loop stability. This section deals with how to determine the output capacitance and ESR needs according to the ripple voltage and load transient requirements.

The output voltage ripple has two components: variations in the charge stored in the output capacitor, and the voltage drop across the capacitor's ESR caused by the current into and out of the capacitor:

$$V_{RIPPLE} = V_{RIPPLE(ESR)} + V_{RIPPLE(C)}$$

$$V_{RIPPLE(ESR)} = I_{RIPPLE} \times R_{ESR}$$

$$V_{RIPPLE(C)} = \frac{I_{RIPPLE}}{8 \times C_{OUT} \times f_{SW}}$$

where C_{OUT} is the output capacitance, and R_{ESR} is the ESR of the output capacitor. In Figure 1's circuit, the inductor ripple current is 0.5A. Assume the voltage-ripple requirement is 2% (peak-to-peak) of the 3.3V output, which corresponds to 66mV total peak-to-peak ripple. Assuming that the ESR ripple component and the capacitive ripple component each should be less than 50% of the 66mV total peak-to-peak ripple, then the ESR should be less than 66mΩ and the output capacitance should be more than 7.6µF to meet the total ripple requirement. A 22µF ceramic capacitor with ESR (including PC board trace resistance) of 10mΩ is selected for the standard application circuit in Figure 1, which easily meets the voltage ripple requirement.

The step-down regulator's output capacitance and ESR also affect the voltage undershoot and overshoot when the load steps up and down abruptly. The undershoot and overshoot have three components: the voltage steps caused by ESR, the voltage undershoot and overshoot due to the current-mode control's AC load regulation, and the voltage sag and soar due to the finite capacitance and inductor slew rate.

The amplitude of the ESR steps is a function of the load step and the ESR of the output capacitor:

$$V_{ESR_STEP} = \Delta I_{LOAD} \times R_{ESR}$$

The amplitude of the sag due to the finite output capacitance and inductor slew rate is a function of the load step, the output capacitor value, the inductor value, the input-to-output voltage differential, and the maximum duty cycle:

$$V_{SAG_LC} = \frac{L \times (\Delta I_{LOAD})^2}{2 \times C_{OUT} \times (V_{IN(MIN)} \times D_{MAX} - V_{OUT})}$$

The amplitude of the undershoot due to the AC load regulation is a function of the high-side MOSFET $R_{DS(ON)}$, the gain of the current-sense amplifier A_{VCS}, the change of the slope compensation during the undershoot (ΔSC_{UNDER}), the transconductance of the error

amplifier g_m, the compensation resistor R_{COMP}, the FB regulation V_{FB}, and the output voltage set point V_{OUT}:

$$V_{UNDER_AC} = \frac{V_{OUT} \times \left(\begin{matrix} A_{VCS} \times R_{DS(ON)} \times \Delta I_{LOAD} \\ +\Delta SC_{UNDER} \end{matrix} \right)}{V_{FB} \times R_{COMP} \times g_m}$$

Use the following to calculate the slope compensation change during the sag:

$$\Delta SC_{UNDER} = 437.5mV \times \left(D_{UNDER} - \frac{V_{OUT}}{V_{IN}} \right)$$

where D_{UNDER} is the duty cycle at the valley of the sag, which is usually 50%.

The actual undershoot is always equal to or bigger than the worst of V_{ESR_STEP}, V_{SAG_LC}, and V_{UNDER_AC}.

The amplitude of the soar due to the finite output capacitance and inductor slew rate is a function of the load step, the output capacitor value, the inductor value, and the output voltage:

$$V_{SOAR_LC} = \frac{L \times (\Delta I_{LOAD})^2}{2 \times C_{OUT} \times V_{OUT}}$$

The amplitude of the overshoot due to the AC load regulation is:

$$V_{OVER_AC} = \frac{V_{OUT} \times \left(\begin{matrix} A_{VCS} \times R_{DS(ON)} \times \Delta I_{LOAD} \\ +\Delta SC_{OVER} \end{matrix} \right)}{V_{FB} \times R_{COMP} \times g_m}$$

where ΔSC_{OVER} is the change of the slope compensation during the overshoot, given by:

$$\Delta SC_{OVER} = 437.5mV \times \left(\frac{V_{OUT}}{V_{IN}} - D_{OVER} \right)$$

where D_{OVER} is the duty cycle at the peak of the overshoot, which is typically 0%.

Similarly, the actual overshoot is always equal to or bigger than the worst of V_{ESR_STEP}, V_{SOAR_LC}, and V_{OVER_AC}.

Given the component values in the circuit of Figure 1, during a 1.5A step load transient, the voltage step due to capacitor ESR is negligible. The voltage sag due to finite capacitance and inductor slew rate is 81mV, and the voltage undershoot due to the AC load regulation is 170mV. The total undershoot seen in the *Typical Operating Characteristics* is 170mV. The voltage soar due to finite capacitance and inductor slew rate is 155mV, and the voltage overshoot due to the AC load regulation is 167mV. The total overshoot seen the in the *Typical Operating Characteristics* is 200mV.

Compensation Design

The step-down controller of the MAX1530/MAX1531 uses a peak current-mode control scheme that regulates the output voltage by forcing the required current through the inductor. The MAX1530/MAX1531 use the voltage across the high-side MOSFET's $R_{DS(ON)}$ to sense the inductor current. Using the current-sense amplifier's output signal and the amplified feedback voltage sensed at FB, the control loop sets the peak inductor current by:

$$I_{PEAK} = \frac{(V_{OUT} - V_{OUT(SET)}) \times V_{FB} \times A_{VEA}}{V_{OUT(SET)} \times R_{DS(ON)} \times A_{VCS}}$$

where V_{FB} = 1.238V is the FB regulation voltage, A_{VCS} is the gain of the current-sense amplifier (3.5 typical), A_{VEA} is the DC gain of the error amplifier (2000 typ), $V_{OUT(SET)}$ is the output voltage set point, and $R_{DS(ON)}$ is the on-resistance of the high-side MOSFET.

The total DC loop gain (A_{DC}) is approximately:

$$A_{DC} = \frac{V_{FB} \times R_{LE} \times A_{VEA}}{V_{OUT(SET)} \times R_{DS(ON)} \times A_{VCS}}$$

R_{LE} is the equivalent load resistance, given by:

$$R_{LE} = \left(\frac{V_{OUT}}{I_{LOAD(MAX)}} \right) \| \left(\frac{L \times f_{SW}}{n \times D' - D} \right)$$

In the above equation, D' = 1 - D, n is a factor determined by the slope compensation m_C and the inductor current ramp m_1, as shown below:

$$n = 1 + \frac{m_C}{m_1}$$

The slope compensation of the MAX1530/MAX1531 is 219mV/µs. The inductor current ramp is a function of the input voltage, output voltage, inductance, high-side MOSFET on-resistance $R_{DS(ON)}$, and the gain of the current-sense amplifier A_{VCS}, and is:

$$m_1 = \frac{V_{IN} - V_{OUT}}{L} \times R_{DS(ON)} \times A_{VCS}$$

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Current-mode control has the effect of splitting the complex pole pair of the output LC filter into a single low-frequency pole and a single high-frequency pole. The low-frequency current-mode pole depends on output capacitor C_{OUT} and the equivalent load resistance R_{LE}, given by the following:

$$f_{POLE(LOW)} = \frac{1}{2\pi \times R_{LE} \times C_{OUT}}$$

The high-frequency current-mode pole is given by:

$$f_{POLE(HIGH)} = \frac{f_{SW}}{2\pi \times n \times D'}$$

The COMP pin, which is the output of the IC's internal transconductance error amplifier, is used to stabilize the control loop. A series resistor (R11) and capacitor (C10) are connected between COMP and AGND to form a pole-zero pair. Another pole-zero pair can be added by connecting a feed-forward capacitor (C23) in parallel with feedback resistor R1. The compensation resistor and capacitors are selected to optimize the loop stability.

The compensation capacitor (C10) creates a dominant pole at very low frequency (a few hertz). The zero formed by R11 and C10 cancels the low-frequency current-mode pole. The zero formed by R1 and C23 cancels the high-frequency current-mode pole and introduces a preferable higher frequency pole. In applications where ceramic capacitors are used, the ESR zero is usually not a concern because the ESR zero occurs at very high frequency. If the ESR zero does not occur at a frequency at least one decade above the crossover, connect a second parallel capacitor (C2) between COMP and AGND to cancel the ESR zero. The component values shown in the standard application circuits (Figure 1 and 2) yield stable operation and fast transient response over a broad range of input-to-output voltages.

To design a compensation network for other components or applications, use the following procedure to achieve stable operation:

1) Select the crossover frequency $f_{CROSSOVER}$ (bandwidth) to be 1/5th the switching frequency f_{SW} or less:

$$f_{CROSSOVER} \le \frac{f_{SW}}{5}$$

Unnecessarily high bandwidth can increase noise sensitivity while providing little benefit. Good transient response with low amounts of output capacitance is achieved with a crossover frequency between 20kHz and 100kHz. The series compensation capacitor (C10) generates a dominant pole that sets the desired crossover frequency. Determine C10 using the following expression:

$$C10 \approx \frac{g_m \times A_{DC}}{2\pi \times f_{CROSSOVER} \times A_{VEA}}$$

where g_m is the error amplifier's transconductance (100µS typ).

2) The compensation resistor R11, together with capacitor C10, provides a zero that is used to cancel the low-frequency current-mode pole. Determine R11 using the following expression:

$$R11 \approx \frac{1}{2\pi \times f_{POLE(LOW)} \times C10}$$

3) Because the error amplifier has limited output current (16µA typ), small values of R11 can prevent the error amplifier from providing an immediate COMP voltage change required for good transient response with minimal output capacitance. If the calculated R11 value is less than 100kΩ, use 100kΩ and recalculate C10 using the following formula:

$$C10 \approx \frac{1}{2\pi \times f_{POLE(LOW)} \times 100k\Omega}$$

Changing C10 also changes the crossover frequency; the new crossover frequency is:

$$f_{CROSSOVER} = \frac{g_m \times A_{DC}}{2\pi \times C10 \times A_{VEA}}$$

The calculated crossover frequency should be less than 1/5th the switching frequency. There are two ways to lower the crossover frequency if the calculated value is greater than 1/5th the switching frequency: increase the high-side MOSFET $R_{DS(ON)}$, or increase the output capacitance. Increasing $R_{DS(ON)}$ reduces the DC loop gain, which results in lower crossover frequency. Increasing output capacitance reduces the frequency of the lower low-frequency current-mode pole, which also results in lower crossover frequency. The following formula gives the

crossover frequency as a function the MOSFET $R_{DS(ON)}$ and the output capacitance:

$$f_{CROSSOVER} = \frac{g_m \times V_{FB} \times R11}{2\pi \times A_{VCS} \times V_{OUT(SET)} \times C_{OUT} \times R_{DS(ON)}}$$

Change one or both of these circuit parameters to obtain the desired crossover. Recalculate ADC and repeat steps 1 to 3 after making the changes.

4) If $f_{POLE(HIGH)}$ is less than the crossover frequency, cancel the pole with a feed-forward zero. Determine the value of C23 (feedback capacitor) using the following:

$$C23 \approx \frac{1}{2\pi \times f_{POLE(HIGH)} \times R1}$$

C23 also forms a secondary pole with R1 and R2 given by the following:

$$f_{POLE_SEC} = \frac{1}{2\pi \times (R1 \parallel R2) \times C23}$$

The frequency of this pole should be above the crossover frequency for loop stability. The position of this pole is related to the high-frequency current-mode pole, which is determined by the inductor current ramp signal. The inductor current ramp signal must satisfy the following condition to ensure the pole occurs above the crossover frequency:

$$m1 > \frac{2\pi \times D' \times R2 \times f_{CROSSOVER} \times m_C}{(R1+R2) \times f_{SW} - 2\pi \times D' \times R2 \times f_{CROSSOVER}}$$

If the frequency of the secondary pole is below the crossover frequency, the frequency of the secondary pole must be moved higher, or the crossover frequency must be moved lower. There are two ways to increase the frequency of the secondary pole: increase the high-side MOSFET $R_{DS(ON)}$, or reduce the step-down inductance, L. As explained before, for given input and output voltages, the current ramp signal is proportional to the high-side MOSFET $R_{DS(ON)}$, and inversely proportional to the inductance. If the pole occurs below the crossover frequency, the current feedback signal is too small. Increasing $R_{DS(ON)}$ or reducing the inductance can increase the current feedback signal. To lower the crossover frequency, use the methods described in step 3. Repeat steps 1 to 4 after making the changes.

5) For most applications using tantalum or polymer capacitors, the output capacitor's ESR forms a second zero that occurs either below or close to the crossover frequency. The zero must be cancelled with a pole. Verify the frequency of the output capacitor's ESR zero, which is:

$$f_{ZERO(ESR)} = \frac{1}{2\pi \times C_{OUT} \times R_{ESR}}$$

where R_{ESR} is the ESR of the output capacitor C_{OUT}. If the output capacitor's ESR zero does not occur well after the crossover, add the parallel compensation capacitor (C2) to form another pole to cancel the ESR zero. Calculate the value of C2 using:

$$C2 \approx \frac{C10}{2\pi \times f_{ZERO(ESR)} \times R11 \times C10 - 1}$$

Applications using ceramic capacitors usually have ESR zeros that occur at least one decade above the crossover. Since the ESR zero of ceramic capacitors has little effect on the loop stability, it does not need to be cancelled.

The following is an example. In the circuit of Figure 1, the input voltage is 12V, the output voltage is set to 3.3V, the maximum load current is 1.5A, the typical on-resistance of the high-side MOSFET is 100mΩ, and the inductor is 10µH. The calculated equivalent load resistance is 1.67Ω. The DC loop gain is:

$$A_{DC} \approx \frac{1.238V \times 1.67\Omega \times 2000}{3.3V \times 100m\Omega \times 3.5} = 4180$$

If the chosen crossover frequency is 20kHz (step 1):

$$C10 \approx \frac{100\mu S \times 4180}{2\pi \times 20kHz \times 2000} \approx 1.7nF$$

With a 22µF output capacitor, the output pole of the step-down regulator is (step 2):

$$f_{POLE(OUT)} = \frac{1}{2\pi \times 22\mu F \times 1.67\Omega} = 4.3kHz$$

Calculate R11 using:

$$R11 \approx \frac{1}{2\pi \times 4.3kHz \times 1.7nF} = 22k\Omega$$

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Because R11 is less than 100kΩ, use 100kΩ for R11 and recalculate C10 as (step 3):

$$C10 \approx \frac{1}{2\pi \times 4.3kHz \times 100k\Omega} = 370pF$$

Use the standard value of 470pF for C10 and recalculate the crossover frequency as:

$$f_{CROSSOVER} \approx \frac{100\mu S \times 4180}{2\pi \times 470pF \times 2000} = 70.8kHz$$

Since the crossover frequency is less than 1/5th the switching frequency, 470pF is an acceptable value for C10.

Because the high-frequency pole of the current-mode control is at 64kHz, the feed-forward capacitor is (step 4):

$$C23 \approx \frac{1}{2\pi \times 64kHz \times 17.8k\Omega} = 140pF$$

Use a standard value of 150pF for C23. The pole formed by C23, R1 and R2 occur at 159kHz, above the 70.8kHz crossover frequency.

Because a ceramic output capacitor is used in the circuit of Figure1, the ESR zero occurs well above the crossover frequency, so no additional compensation capacitor (C2) is needed (step 5).

Output Voltage Selection

The MAX1530/MAX1531 step-down regulator's output voltage can be adjusted by connecting a resistive voltage-divider from the output to AGND with the center tap connected to FB (Figure 1). Select R2 in the 5kΩ to 50kΩ range. Calculate R1 with the following equation:

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1 \right)$$

where V_{FB} = 1.238V, and V_{OUT} may vary from 1.238V to approximately 0.6 × V_{IN} (V_{IN} is up to 28V).

Boost-Supply Diode

A signal diode, such as the 1N4148, works well in most applications. If the input voltage goes below 6V, use a small 100mA Schottky diode for slightly improved efficiency and dropout characteristics. Do not use power diodes, such as the 1N5817 or 1N4001, since high junction capacitance can charge up VL to excessive voltages.

Charge Pumps

Selecting the Number of Charge-Pump Stages

For highest efficiency, always choose the lowest number of charge-pump stages that meet the output requirement. The number of positive charge-pump stages is given by:

$$N_{POS} = \frac{V_{POS} + V_{DROPOUT} - V_{IN}}{V_{IN} - 2 \times V_D}$$

where N_{POS} is the number of positive charge-pump stages, V_{POS} is the positive charge-pump output, V_{IN} is the input voltage of the step-down regulator, V_D is the forward voltage drop of the charge-pump diode, and $V_{DROPOUT}$ is the dropout margin for the linear regulator. Use $V_{DROPOUT}$ = 0.3V.

The number of negative charge-pump stages is given by:

$$N_{NEG} = \frac{-V_{NEG} + V_{DROPOUT}}{V_{IN} - 2 \times V_D}$$

where N_{NEG} is the number of negative charge-pump stages, V_{NEG} is the negative charge-pump output, V_{IN} is the input voltage of the step-down regulator, V_D is the forward voltage drop of the charge-pump diode, and $V_{DROPOUT}$ is the dropout margin for the linear regulator. Use $V_{DROPOUT}$ = 0.3V.

The above equations are derived based on the assumption that the first stage of the positive charge pump is connected to V_{IN} and the first stage of the negative charge pump is connected to ground. Sometimes fractional stages are more desirable for better efficiency. This can be done by connecting the first stage to V_{OUT} or another available supply. If the first stage of the positive charger pump is powered from the output of the step-down regulator V_{OUT}, then the equation becomes:

$$N_{POS} = \frac{-V_{POS} + V_{DROPOUT} - V_{OUT}}{V_{IN} - 2 \times V_D}$$

If the first stage of the negative charge pump is powered from the output of the step-down regulator V_{OUT}, then the equation becomes:

$$N_{NEG} = \frac{-V_{NEG} + V_{DROPOUT} + V_{OUT}}{V_{IN} - 2 \times V_D}$$

Flying Capacitors

Increasing the flying capacitor value lowers the effective source impedance and increases the output current capability. Increasing the capacitance indefinitely has a negligible effect on output current capability because the internal switch resistance and the diode impedance place a lower limit on the source impedance. A 0.1µF ceramic capacitor works well in most low-current applications. The voltage rating for a given flying capacitor (CX) must exceed the following:

$$V_{CX} > N \times V_{IN}$$

where N is the stage number in which the flying capacitor appears, and V_{IN} is the input voltage of the step-down regulator.

Charge-Pump Output Capacitors

Increasing the output capacitance or decreasing the ESR reduces the charge pump output ripple voltage and the peak-to-peak transient voltage. With ceramic capacitors, the output voltage ripple is dominated by the capacitance value. Use the following equation to approximate the required capacitor value:

$$C_{OUT} \geq \frac{I_{LOAD}}{2f_{OSC}V_{RIPPLE}}$$

where V_{RIPPLE} is the peak-to-peak value of the output ripple.

Charge-Pump Rectifier Diodes

Use low-cost silicon switching diodes with a current rating equal to or greater than 2 times the average charge-pump input current. If it helps avoid an extra stage, some or all of the diodes can be replaced with Schottky diodes with an equivalent current rating.

Linear Regulator Controllers

Output Voltage Selection

Adjust the positive linear regulator (LR1 to LR4) output voltages by connecting a resistive voltage-divider from the output to AGND with the center tap connected to FBL_ (Figure 1). Select the lower resistor of the divider in the 10kΩ to 30kΩ range. Calculate the upper resistor with the following equation:

$$R_{UPPER} = R_{LOWER} \times \left[\left(V_{OUT_} / V_{FBL_}\right) - 1\right]$$

where $V_{FBL_}$ is 1.238V (typ).

Adjust the negative linear regulator (LR5) output voltage by connecting a resistive voltage-divider from V_{GOFF} to VL with the center tap connected to FBL5 (Figure 1). Select R29 in the 10kΩ to 30kΩ range. Calculate R28 with the following equation:

$$R28 = R29 \times \left[\left(V_{FBL5} - V_{GOFF}\right)/\left(V_L - V_{FBL5}\right)\right]$$

where V_{FBL5} = 125mV and V_L = 5.0V.

Pass Transistor Selection

The pass transistor must meet specifications for DC current gain (h_{FE}), collector-emitter saturation voltage, and power dissipation. The transistor's current gain limits the guaranteed maximum output current to:

$$I_{LOAD(MAX)} = \left(I_{DRV} - \frac{V_{BE}}{R_{BE}}\right) \times h_{FE}$$

where I_{DRV} is the minimum guaranteed base drive current, V_{BE} is the base-emitter voltage of the pass transistor, and R_{BE} is the pullup resistor connected between the transistor's base and emitter. Furthermore, the transistor's current gain increases the linear regulator's DC loop gain (see the *Stability Requirements* section), which may destabilize the output. Therefore, transistors with current gain over 300 at the maximum output current can be difficult to stabilize and are not recommended unless the high gain is needed to meet the load current requirements.

The transistor's saturation voltage at the maximum output current determines the minimum input-to-output voltage differential that the linear regulator supports. Also, the package's power dissipation limits the usable maximum input-to-output voltage differential. The maximum power dissipation capability of the transistor's package and mounting must exceed the actual power dissipation in the device. The power dissipation equals the maximum load current ($I_{LOAD(MAX)}$) times the maximum input-to-output voltage differential:

$$P = I_{LOAD(MAX)} \times \left(V_{LRIN(MAX)} - V_{LROUT}\right)$$

where $V_{LRIN(MAX)}$ is the maximum input voltage of the linear regulator, and V_{LROUT} is the output voltage of the linear regulator.

Output Voltage Ripple

Ideally, the output voltage of a linear regulator should not contain any ripple. In the MAX1530/MAX1531, the step-down regulator's switching noise can couple to the linear regulators, creating output voltage ripple. Following the PC board layout guidelines in the *PC Board Layout and Grounding* section can significantly reduce noise coupling. If there is still an unacceptable

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amount of ripple after the PC board layout has been optimized, consider increasing output capacitance. Adding more capacitance does not eliminate the ripple, but proportionally reduces the amplitude of the ripple. If increasing the output capacitance is not desirable because of space or cost concerns, then consider slowing the turn-on of the step-down DC-to-DC MOSFETs. Slower turn-on leads to smoother LX rising and falling edges and consequently reduces the switching noise. When slowing down MOSFET turn-on, ensure the turn-off time is not affected. Otherwise, the adaptive dead-time circuitry may not work properly and shoot-through may occur. See the MOSFET Gate Drivers section for details on how to slow down the turn-on of both DH and DL.

Stability Requirements

The MAX1530/MAX1531 linear-regulator controllers use an internal transconductance amplifier to drive an external pass transistor. The transconductance amplifier, the pass transistor, the base-emitter resistor, and the output capacitor determine loop stability. The following applies equally to all linear regulators in the MAX1530 and MAX1531. Any differences are highlighted where appropriate.

The transconductance amplifier regulates the output voltage by controlling the pass transistor's base current. The total DC loop gain is approximately:

$$A_{V(LR)} \approx \left(\frac{4}{V_T}\right) \times \left(1 + \frac{I_{BIAS} \times h_{FE}}{I_{LOAD}}\right) \times V_{REF}$$

where V_T is 26mV at room temperature, I_{LOAD} is the output current of the linear regulator, V_{REF} is the linear regulator's internal reference voltage, and I_{BIAS} is the current through the base-to-emitter resistor (R_{BE}). Each of the linear regulator controllers is designed for a different maximum output current so they have different output drive currents and different bias currents (I_{BIAS}). Each controller's bias current can be found in the *Electrical Characteristics*. The current listed in the Conditions column for the FBL_ regulation voltage specification is the individual controller's bias current. The base-to-emitter resistor for each controller should be chosen to set the correct I_{BIAS}:

$$R_{BE} = \frac{V_{BE}}{I_{BIAS}}$$

The output capacitor and the load resistance create the dominant pole in the system. However, the internal amplifier delay, the pass transistor's input capacitance, and the stray capacitance at the feedback node create additional poles in the system, and the output capacitor's ESR generates a zero. For proper operation, use the following steps to ensure the linear regulator's stability:

1) First, calculate the dominant pole set by the linear regulator's output capacitor and the load resistor:

$$f_{POLE(LR)} = \frac{1}{2\pi C_{LR} R_{LOAD}}$$

where C_{LR} is the output capacitance of the linear regulator and R_{LOAD} is the load resistance corresponding to the maximum load current.

The unity-gain crossover of the linear regulator is:

$$f_{CROSSOVER} = A_{V(LDO)} f_{POLE(LDO)}$$

2) The pole created by the internal amplifier delay is about 1MHz:

$$f_{POLE(AMP)} \cong 1MHz$$

3) Next, calculate the pole set by the transistor's input capacitance, the transistor's input resistance, and the base-to-emitter pullup resistor:

$$f_{POLE(C_{IN})} = \frac{1}{2\pi C_{IN}(R_{BE} \,||\, R_{IN})}$$

where $C_{IN} = \frac{g_m}{2\pi f_T}$, $R_{IN} = R_\pi = \frac{h_{FE}}{g_m}$, g_m is the transconductance of the pass transistor, and f_T is the transition frequency. Both parameters can be found in the transistor's data sheet.

Because R_{BE} is much greater than R_{IN}, the above equation can be simplified:

$$f_{POLE(C_{IN})} \approx \frac{1}{2\pi C_{IN} R_{IN}}$$

The equation can be further simplified:

$$f_{POLE(C_{IN})} = \frac{f_T}{h_{FE}}$$

4) Next, calculate the pole set by each linear regulator's feedback resistance and the capacitance ($C_{FBL_}$) between FBL_ and AGND (approximately 5pF including stray capacitance):

$$f_{POLE(FBL1)} = \frac{1}{2\pi C_{FBL1}(R9 \| R10)}$$

$$f_{POLE(FBL2)} = \frac{1}{2\pi C_{FBL2}(R18 \| R19)}$$

$$f_{POLE(FBL3)} = \frac{1}{2\pi C_{FBL3}(R25 \| R26)}$$

$$f_{POLE(FBL4)} = \frac{1}{2\pi C_{FBL4}(R22 \| R23)} \text{ and}$$

$$f_{POLE(FBL5)} = \frac{1}{2\pi C_{FBL5}(R28 \| R29)}$$

5) Next, calculate the zero caused by the output capacitor's ESR:

$$f_{ESR_ZERO} = \frac{1}{2\pi C_{LR} R_{ESR}}$$

where R_{ESR} is the equivalent series resistance of C_{LR}.

6) To ensure stability, choose C_{LR} large enough so that the crossover occurs well before the poles and zero calculated in steps 2) to 5). The poles in steps 3) and 4) generally occur at several megahertz and using ceramic capacitors ensures the ESR zero occurs at several megahertz as well. Placing the crossover below 500kHz is sufficient to avoid the amplifier-delay pole and generally works well, unless unusual component choices or extra capacitances move the other poles or zero below 1MHz.

PC Board Layout and Grounding

Careful PC board layout is important for proper operation. Use the following guidelines for good PC board layout:

1) Place the high-power components of the step-down regulator (input capacitors, MOSFETs, inductor, and output capacitors) first, with any grounded connections adjacent. Connect these components with short, wide traces. Avoid using vias in the high-current paths. If vias are unavoidable, use many vias in parallel to reduce resistance and inductance.

2) Create islands for the analog ground (AGND), power ground (PGND), and individual linear regulator grounds. Connect all these ground areas (islands) together at only one location, which is a via connected to the backside pad of the device. All voltage-feedback dividers should be connected to the analog ground island. The step-down regulator's input and output capacitors, and the charge pump components should be a wide power ground plane. The power ground plane should be connected to the power ground pin (PGND) with a wide trace. Maximizing the width of the power ground traces improves efficiency, and reduces output voltage ripple and noise spikes. All other ground connections, such as the VL and IN pin bypass capacitor and the linear regulator output capacitors, should be star-connected to the backside of the device with wide traces. Make no other connections between these separate ground planes.

3) Place the IN pin and VL pin bypass capacitors within 5mm from the IC and connect them to their respective pins with short, direct connections.

4) Since both MOSFETs are used for current sensing, care must be taken to ensure that noise and DC errors do not corrupt the sense signals. Place both MOSFETs close to the IC. Connect PGND to the source of the low-side MOSFET with a short, wide trace. Connect DL to the gate of the low-side MOSFET with a short, wide trace. Ensure that the traces from DL to low-side MOSFET to PGND total no more than 50 squares. Connect LX close to the connection point between the low-side and high-side MOSFETs with a short, wide trace. Connect DH to the gate of the high-side MOSFET with a short, wide trace. Ensure that the traces from DH to high-side MOSFET to LX total no more than 50 squares (50 squares corresponds to 20 mils wide if the total trace is 1in long).

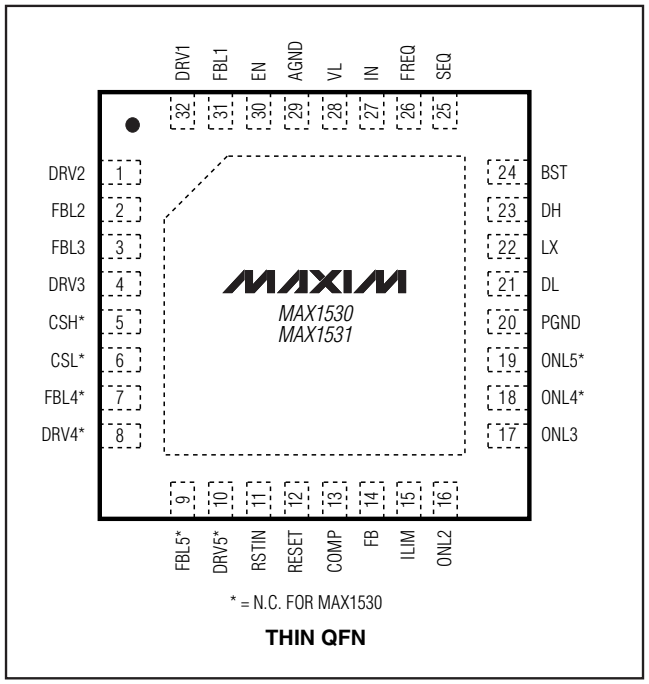
5) Place all feedback voltage-divider resistors as close to their respective feedback pins as possible. The divider's center trace should be kept short. Placing the resistors far away causes their FB traces to become antennas that can pick up switching noise. Care should be taken to avoid running any feedback trace near LX or the switching nodes in the charge pumps.

6) Minimize the length and maximize the width of the traces between the output capacitors and the load for best transient responses.

7) Minimize the size of the LX node while keeping it wide and short. Keep the LX node away from feedback nodes and analog ground. Use DC traces as shield if necessary.

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Pin Configuration



THIN QFN

Chip Information

PROCESS: BiCMOS

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
32 TQFN	T-3255-4	**21-0140**

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	0	Initial release	—
1	11/09	Changing an existing part to an automotive-qualified part (/V)	1, 13, 32, 33, 34

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